

LTC2057/LTC2057HV

ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage (V^+ to V^-)	Output Short-Circuit Duration	Indefinite
LTC2057	Operating Temperature Range (Note 2)	
LTC2057HV	LTC2057I/LTC2057HVI	-40°C to 85°C
Input Voltage	LTC2057H/LTC2057HVH	-40°C to 125°C
$-IN$, $+IN$	Storage Temperature Range	-65°C to 150°C
$\overline{SD}$, $SDCOM$	Lead Temperature (Soldering, 10 sec)	300°C
Input Current		
$-IN$, $+IN$		
$\overline{SD}$, $SDCOM$		
Differential Input Voltage		
$-IN - +IN$		
$\overline{SD} - SDCOM$		

PIN CONFIGURATION

TOP VIEW DD PACKAGE 8-LEAD (3mm $\times$ 3mm) PLASTIC DFN $T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 43^{\circ}\text{C/W}$ EXPOSED PAD (PIN 9) IS V^- PCB CONNECTION REQUIRED	TOP VIEW MS8 PACKAGE 8-LEAD PLASTIC MSOP $T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 163^{\circ}\text{C/W}$
TOP VIEW S8 PACKAGE 8-LEAD PLASTIC SO $T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 120^{\circ}\text{C/W}$	TOP VIEW MS PACKAGE 10-LEAD PLASTIC MSOP $T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 160^{\circ}\text{C/W}$

ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC2057IDD#PBF	LTC2057IDD#TRPBF	LGCZ	8-Lead Plastic DFN (3mm × 3mm)	–40°C to 85°C
LTC2057HVIDD#PBF	LTC2057HVIDD#TRPBF	LGDB	8-Lead Plastic DFN (3mm × 3mm)	–40°C to 85°C
LTC2057HDD#PBF	LTC2057HDD#TRPBF	LGCZ	8-Lead Plastic DFN (3mm × 3mm)	–40°C to 125°C
LTC2057HVHDD#PBF	LTC2057HVHDD#TRPBF	LGDB	8-Lead Plastic DFN (3mm × 3mm)	–40°C to 125°C
LTC2057IMS#PBF	LTC2057IMS#TRPBF	LTFGK	8-Lead Plastic MSOP	–40°C to 85°C
LTC2057HVIMS8#PBF	LTC2057HVIMS8#TRPBF	LTGDC	8-Lead Plastic MSOP	–40°C to 85°C
LTC2057HMS8#PBF	LTC2057HMS8#TRPBF	LTFGK	8-Lead Plastic MSOP	–40°C to 125°C
LTC2057HVHMS8#PBF	LTC2057HVHMS8#TRPBF	LTGDC	8-Lead Plastic MSOP	–40°C to 125°C
LTC2057IMS#PBF	LTC2057IMS#TRPBF	LTGCX	10-Lead Plastic MSOP	–40°C to 85°C
LTC2057HVIMS#PBF	LTC2057HVIMS#TRPBF	LTGCY	10-Lead Plastic MSOP	–40°C to 85°C
LTC2057HMS#PBF	LTC2057HMS#TRPBF	LTGCX	10-Lead Plastic MSOP	–40°C to 125°C
LTC2057HVHMS#PBF	LTC2057HVHMS#TRPBF	LTGCY	10-Lead Plastic MSOP	–40°C to 125°C
LTC2057IS8#PBF	LTC2057IS8#TRPBF	2057	8-Lead Plastic Small Outline	–40°C to 85°C
LTC2057HVIS8#PBF	LTC2057HVIS8#TRPBF	2057HV	8-Lead Plastic Small Outline	–40°C to 85°C
LTC2057HS8#PBF	LTC2057HS8#TRPBF	2057	8-Lead Plastic Small Outline	–40°C to 125°C
LTC2057HVHS8#PBF	LTC2057HVHS8#TRPBF	2057HV	8-Lead Plastic Small Outline	–40°C to 125°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeand reel/>

LTC2057/LTC2057HV

ELECTRICAL CHARACTERISTICS (LTC2057/LTC2057HV) The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. Unless otherwise noted, $V_S = \pm 2.5\text{V}$; $V_{CM} = V_{OUT} = 0\text{V}$.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 3)			0.5	4	μV
$\Delta V_{OS}/\Delta T$	Average Input Offset Voltage Drift (Note 3)	-40°C to 125°C	●		0.015	$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current (Note 4)	-40°C to 85°C	●	30	200	pA
		-40°C to 125°C	●		300	pA
					3.5	nA
I_{OS}	Input Offset Current (Note 4)	-40°C to 85°C	●	60	400	pA
		-40°C to 125°C	●		460	pA
					1.0	nA
i_n	Input Noise Current Spectral Density	1kHz		170		$\text{fA}/\sqrt{\text{Hz}}$
e_n	Input Noise Voltage Spectral Density	1kHz		11		$\text{nV}/\sqrt{\text{Hz}}$
$e_{n\text{ P-P}}$	Input Noise Voltage	DC to 10Hz		200		$\text{nV}_{\text{P-P}}$
C_{IN}	Differential Input Capacitance			3		pF
	Common Mode Input Capacitance			3		pF
CMRR	Common Mode Rejection Ratio (Note 5)	$V_{CM} = V^- - 0.1\text{V}$ to $V^+ - 1.5\text{V}$	●	114	150	dB
		-40°C to 125°C		111		dB
PSRR	Power Supply Rejection Ratio (Note 5)	$V_S = 4.75\text{V}$ to 36V	●	133	160	dB
		-40°C to 125°C		129		dB
A_{VOL}	Open Loop Voltage Gain (Note 5)	$V_{OUT} = V^- + 0.2\text{V}$ to $V^+ - 0.2\text{V}$, $R_L = 1\text{k}\Omega$	●	118	150	dB
		-40°C to 125°C		117		dB
$V_{OL} - V^-$	Output Voltage Swing Low	No Load	●	0.2	10	mV
		-40°C to 125°C			15	mV
		$I_{SINK} = 1\text{mA}$	●	35	60	mV
		-40°C to 125°C	●		90	mV
		$I_{SINK} = 5\text{mA}$	●	180	270	mV
		-40°C to 85°C	●		365	mV
		-40°C to 125°C	●		415	mV
$V^+ - V_{OH}$	Output Voltage Swing High	No Load	●	0.2	10	mV
		-40°C to 125°C			15	mV
		$I_{SOURCE} = 1\text{mA}$	●	50	75	mV
		-40°C to 125°C	●		115	mV
		$I_{SOURCE} = 5\text{mA}$	●	250	345	mV
		-40°C to 85°C	●		470	mV
		-40°C to 125°C	●		535	mV
I_{SC}	Short Circuit Current			17	26	mA
SR_{RISE}	Rising Slew Rate	$A_V = -1$, $R_L = 10\text{k}\Omega$		1.2		$\text{V}/\mu\text{s}$
SR_{FALL}	Falling Slew Rate	$A_V = -1$, $R_L = 10\text{k}\Omega$		0.45		$\text{V}/\mu\text{s}$
GBW	Gain Bandwidth Product			1.5		MHz
f_C	Internal Chopping Frequency			100		kHz
I_S	Supply Current	No Load	●	0.8	1.21	mA
		-40°C to 85°C	●		1.50	mA
		-40°C to 125°C	●		1.70	mA
		In Shutdown Mode	●	2.5		μA
		-40°C to 85°C	●		5.6	μA
		-40°C to 125°C	●		6.5	μA
V_{SDL}	Shutdown Threshold ($\overline{\text{SD}} - \text{SDCOM}$) Low	-40°C to 125°C	●		0.8	V
V_{SDH}	Shutdown Threshold ($\overline{\text{SD}} - \text{SDCOM}$) High	-40°C to 125°C	●	2		V
	SDCOM Voltage Range	-40°C to 125°C	●	V^-	$V^+ - 2\text{V}$	V
$I_{\overline{\text{SD}}}$	$\overline{\text{SD}}$ Pin Current	-40°C to 125°C , $V_{\overline{\text{SD}}} - V_{\text{SDCOM}} = 0$	●	-2	-0.5	μA
I_{SDCOM}	SDCOM Pin Current	-40°C to 125°C , $V_{\overline{\text{SD}}} - V_{\text{SDCOM}} = 0$	●	0.5	2	μA

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 3)			0.5	4.5	μV
$\Delta V_{OS}/\Delta T$	Average Input Offset Voltage Drift (Note 3)	-40°C to 125°C	●		0.015	$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current (Note 4)	-40°C to 85°C -40°C to 125°C	● ●	30	200 360 6.0	pA pA nA
I_{OS}	Input Offset Current (Note 4)	-40°C to 85°C -40°C to 125°C	● ●	60	400 480 1.5	pA pA nA
i_n	Input Noise Current Spectral Density	1kHz		150		$\text{fA}/\sqrt{\text{Hz}}$
e_n	Input Noise Voltage Spectral Density	1kHz		12		$\text{nV}/\sqrt{\text{Hz}}$
$e_{n\text{ P-P}}$	Input Noise Voltage	DC to 10Hz		210		$\text{nV}_{\text{P-P}}$
C_{IN}	Differential Input Capacitance Common Mode Input Capacitance			3 3		pF pF
CMRR	Common Mode Rejection Ratio (Note 5)	$V_{CM} = V^- - 0.1\text{V}$ to $V^+ - 1.5\text{V}$ -40°C to 125°C	●	128 126	150	dB dB
PSRR	Power Supply Rejection Ratio (Note 5)	$V_S = 4.75\text{V}$ to 36V -40°C to 125°C	●	133 129	160	dB dB
A_{VOL}	Open Loop Voltage Gain (Note 5)	$V_{OUT} = V^- + 0.25\text{V}$ to $V^+ - 0.25\text{V}$, $R_L = 10\text{k}\Omega$ -40°C to 125°C	●	130 128	150	dB dB
$V_{OL} - V^-$	Output Voltage Swing Low	No Load -40°C to 125°C $I_{SINK} = 1\text{mA}$ -40°C to 125°C $I_{SINK} = 5\text{mA}$ -40°C to 85°C -40°C to 125°C	● ● ● ● ●	2 35 175	12 45 60 100 255 360 435	mV mV mV mV mV mV mV
$V^+ - V_{OH}$	Output Voltage Swing High	No Load -40°C to 125°C $I_{SOURCE} = 1\text{mA}$ -40°C to 125°C $I_{SOURCE} = 5\text{mA}$ -40°C to 85°C -40°C to 125°C	● ● ● ● ●	3 50 235	15 45 75 125 335 465 560	mV mV mV mV mV mV mV
I_{SC}	Short Circuit Current			19	30	mA
SR_{RISE}	Rising Slew Rate	$A_V = -1$, $R_L = 10\text{k}\Omega$		1.3		$\text{V}/\mu\text{s}$
SR_{FALL}	Falling Slew Rate	$A_V = -1$, $R_L = 10\text{k}\Omega$		0.45		$\text{V}/\mu\text{s}$
GBW	Gain Bandwidth Product			1.5		MHz
f_C	Internal Chopping Frequency			100		kHz
I_S	Supply Current	No Load -40°C to 85°C -40°C to 125°C In Shutdown Mode -40°C to 85°C -40°C to 125°C	● ● ● ● ●	0.88 3	1.35 1.65 1.83 8 9	mA mA mA μA μA μA
V_{SDL}	Shutdown Threshold ($\overline{\text{SD}}$ – SDCOM) Low	-40°C to 125°C	●		0.8	V
V_{SDH}	Shutdown Threshold ($\overline{\text{SD}}$ – SDCOM) High	-40°C to 125°C	●	2		V
	SDCOM Voltage Range	-40°C to 125°C	●	V^-	$V^+ - 2\text{V}$	V
$I_{\overline{\text{SD}}}$	$\overline{\text{SD}}$ Pin Current	-40°C to 125°C , $V_{\overline{\text{SD}}} - V_{\text{SDCOM}} = 0$	●	-2.0	-0.5	μA
I_{SDCOM}	SDCOM Pin Current	-40°C to 125°C , $V_{\overline{\text{SD}}} - V_{\text{SDCOM}} = 0$	●	0.5	2	μA

LTC2057/LTC2057HV

ELECTRICAL CHARACTERISTICS (LTC2057HV) The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. Unless otherwise noted, $V_S = \pm 30\text{V}$; $V_{CM} = V_{OUT} = 0\text{V}$.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 3)			0.5	5	μV
$\Delta V_{OS}/\Delta T$	Average Input Offset Voltage Drift (Note 3)	-40°C to 125°C	●		0.025	$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current (Note 4)	-40°C to 85°C -40°C to 125°C	● ●	30	200 455 11	pA pA nA
I_{OS}	Input Offset Current (Note 4)	-40°C to 85°C -40°C to 125°C	● ●	60	400 500 3	pA pA nA
i_n	Input Noise Current Spectral Density	1kHz		130		$\text{fA}/\sqrt{\text{Hz}}$
e_n	Input Noise Voltage Spectral Density	1kHz		13		$\text{nV}/\sqrt{\text{Hz}}$
e_n P-P	Input Noise Voltage	DC to 10Hz		220		nV_{P-P}
C_{IN}	Differential Input Capacitance Common Mode Input Capacitance			3 3		pF pF
CMRR	Common Mode Rejection Ratio (Note 5)	$V_{CM} = V^- - 0.1\text{V}$ to $V^+ - 1.5\text{V}$ -40°C to 125°C	●	133 131	150	dB dB
PSRR	Power Supply Rejection Ratio (Note 5)	$V_S = 4.75\text{V}$ to 60V -40°C to 125°C	●	138 136	160	dB dB
A_{VOL}	Open Loop Voltage Gain (Note 5)	$V_{OUT} = V^- + 0.25\text{V}$ to $V^+ - 0.25\text{V}$, $R_L = 10\text{k}\Omega$ -40°C to 125°C	●	135 130	150	dB dB
$V_{OL} - V^-$	Output Voltage Swing Low	No Load -40°C to 125°C $I_{SINK} = 1\text{mA}$ -40°C to 125°C $I_{SINK} = 5\text{mA}$ -40°C to 85°C -40°C to 125°C	● ● ● ● ●	3 35 175	15 45 60 105 260 370 445	mV mV mV mV mV mV mV
$V^+ - V_{OH}$	Output Voltage Swing High	No Load -40°C to 125°C $I_{SOURCE} = 1\text{mA}$ -40°C to 125°C $I_{SOURCE} = 5\text{mA}$ -40°C to 85°C -40°C to 125°C	● ● ● ● ●	3 50 235	15 45 75 130 335 475 575	mV mV mV mV mV mV mV
I_{SC}	Short Circuit Current			19	30	mA
SR_{RISE}	Rising Slew Rate	$A_V = -1$, $R_L = 10\text{k}\Omega$		1.3		$\text{V}/\mu\text{s}$
SR_{FALL}	Falling Slew Rate	$A_V = -1$, $R_L = 10\text{k}\Omega$		0.45		$\text{V}/\mu\text{s}$
GBW	Gain Bandwidth Product			1.5		MHz
f_C	Internal Chopping Frequency			100		kHz
I_S	Supply Current	No Load -40°C to 85°C -40°C to 125°C In Shutdown Mode -40°C to 85°C -40°C to 125°C	● ● ● ● ●	0.90 3	1.40 1.73 1.92 9 11	mA mA mA μA μA μA
V_{SDL}	Shutdown Threshold (SD – SDCOM) Low	-40°C to 125°C	●		0.8	V
V_{SDH}	Shutdown Threshold (SD – SDCOM) High	-40°C to 125°C	●	2		V
	SDCOM Voltage Range	-40°C to 125°C	●	V^-	$V^+ - 2\text{V}$	V
I_{SD}	$\overline{\text{SD}}$ Pin Current	-40°C to 125°C , $V_{SD} - V_{SDCOM} = 0$	●	-2	-0.5	μA
I_{SDCOM}	SDCOM Pin Current	-40°C to 125°C , $V_{SD} - V_{SDCOM} = 0$	●	0.5	2	μA

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ELECTRICAL CHARACTERISTICS

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The LTC2057I/LTC2057HVI are guaranteed to meet specified performance from -40°C to 85°C . The LTC2057H/LTC2057HVH are guaranteed to meet specified performance from -40°C to 125°C .

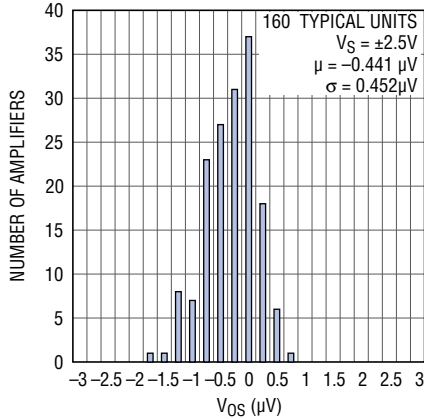
Note 3: These parameters are guaranteed by design. Thermocouple effects preclude measurements of these voltage levels during automated testing. V_{OS} is measured to a limit determined by test equipment capability.

Note 4: These specifications are limited by automated test system capability. Leakage currents and thermocouple effects reduce test accuracy. For tighter specifications, please contact LTC Marketing.

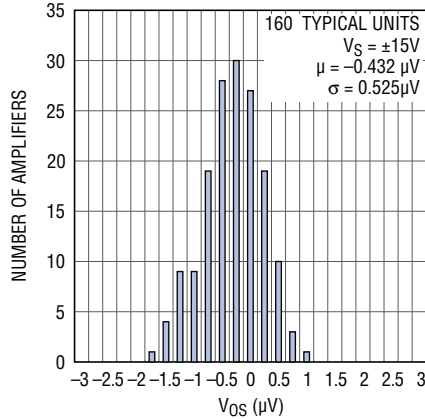
Note 5: Minimum specifications for these parameters are limited by the capabilities of the automated test system, which has an accuracy of approximately $10\mu\text{V}$ for V_{OS} measurements. For reference, $10\mu\text{V}/60\text{V}$ is 136dB, $10\mu\text{V}/30\text{V}$ is 130dB, and $10\mu\text{V}/5\text{V}$ is 114dB.

TYPICAL PERFORMANCE CHARACTERISTICS

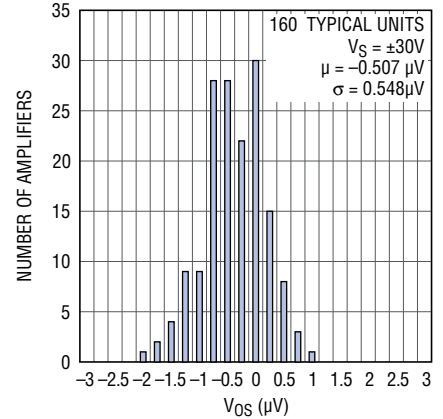
Input Offset Voltage Distribution



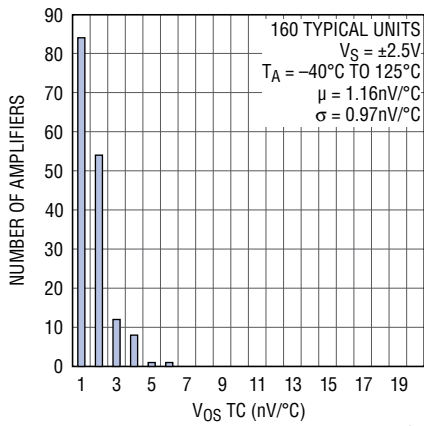
Input Offset Voltage Distribution



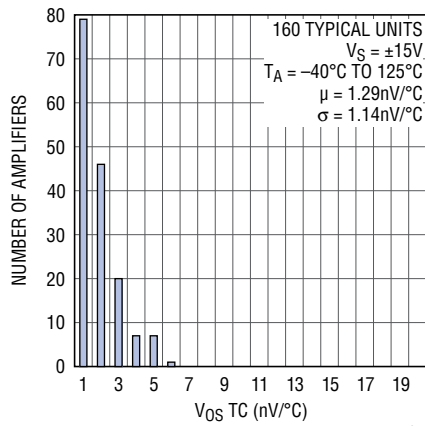
Input Offset Voltage Distribution



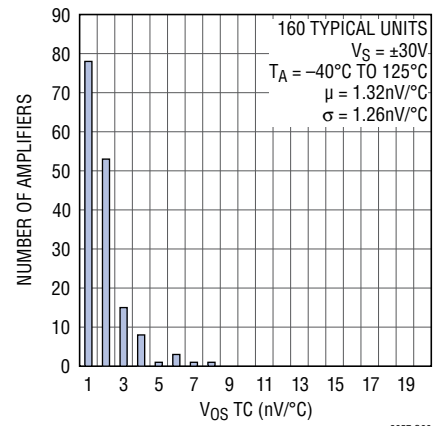
Input Offset Voltage Drift Distribution



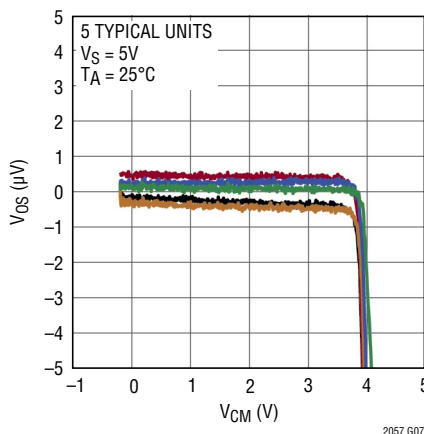
Input Offset Voltage Drift Distribution



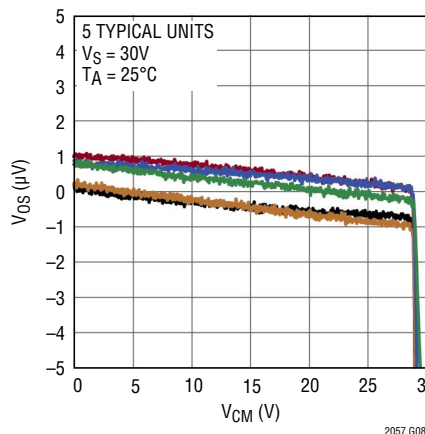
Input Offset Voltage Drift Distribution



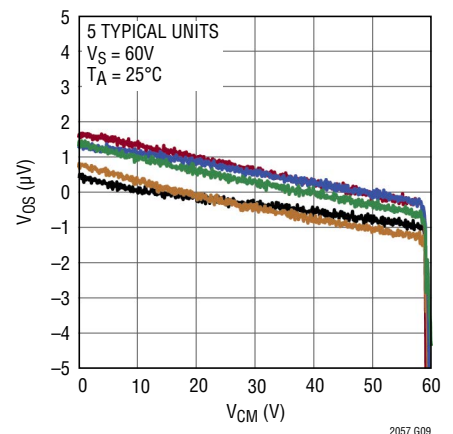
Input Offset Voltage vs Input Common Mode Voltage



Input Offset Voltage vs Input Common Mode Voltage

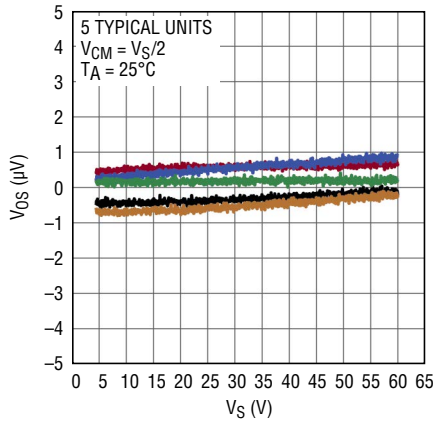


Input Offset Voltage vs Input Common Mode Voltage

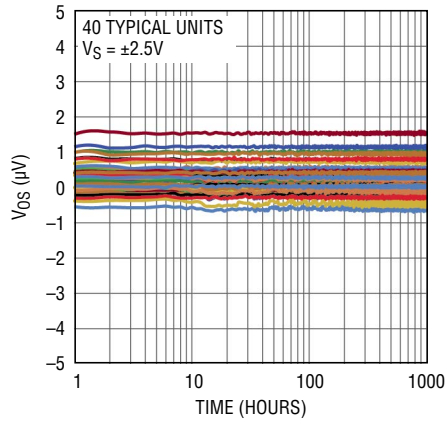


TYPICAL PERFORMANCE CHARACTERISTICS

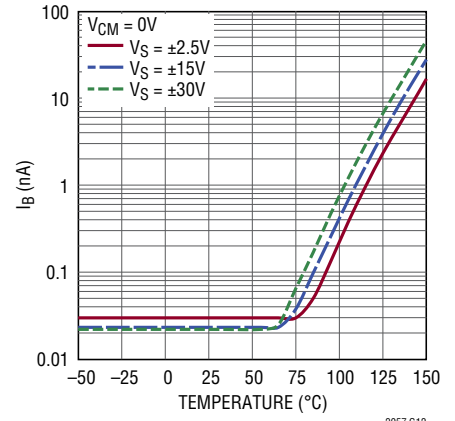
Input Offset Voltage vs Supply Voltage



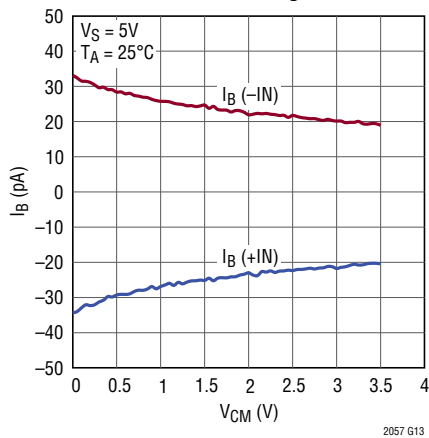
Long-Term Input Offset Voltage Drift



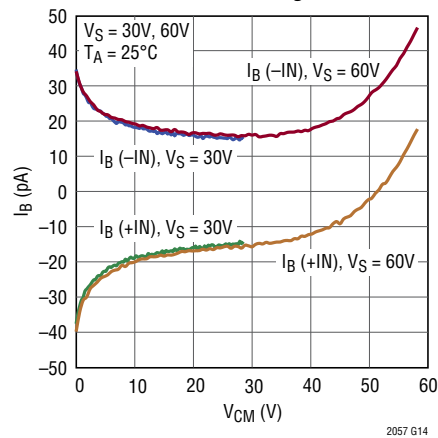
Input Bias Current vs Temperature



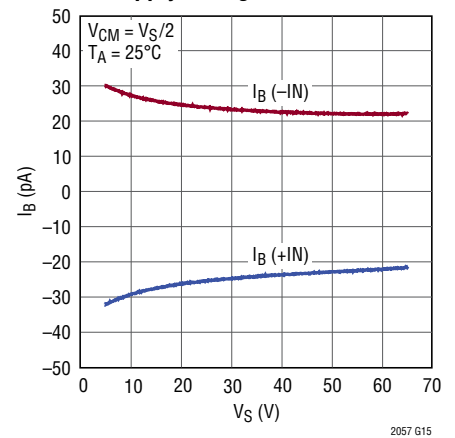
Input Bias Current vs Input Common Mode Voltage



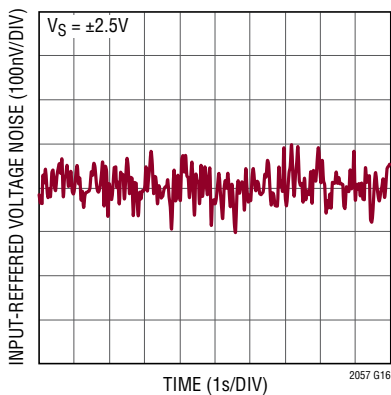
Input Bias Current vs Input Common Mode Voltage



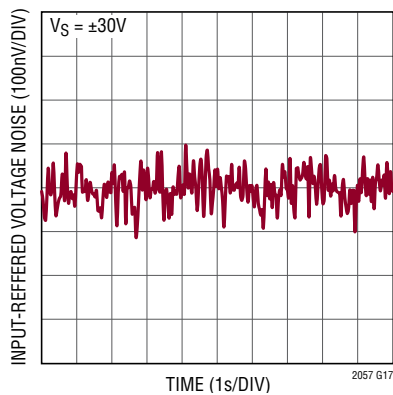
Input Bias Current vs Supply Voltage



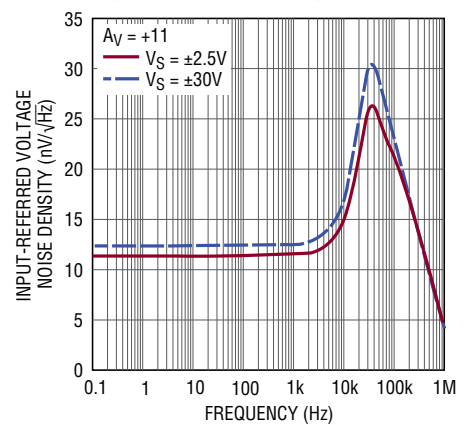
DC to 10Hz Voltage Noise



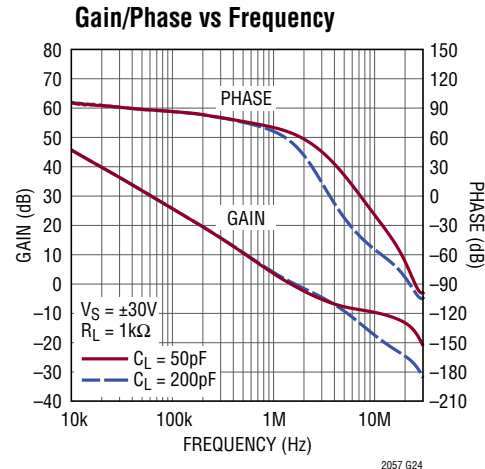
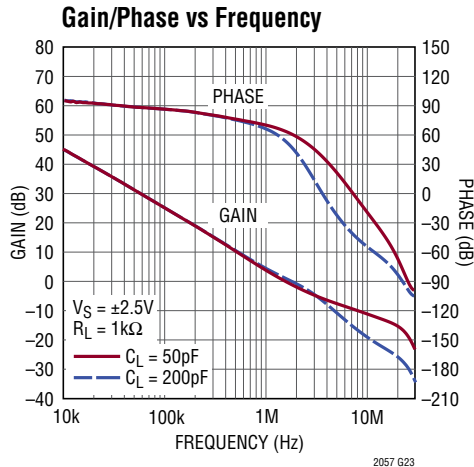
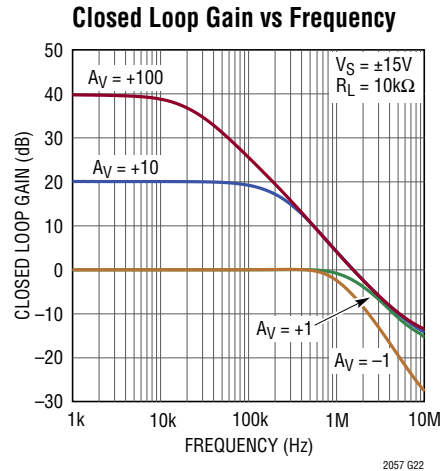
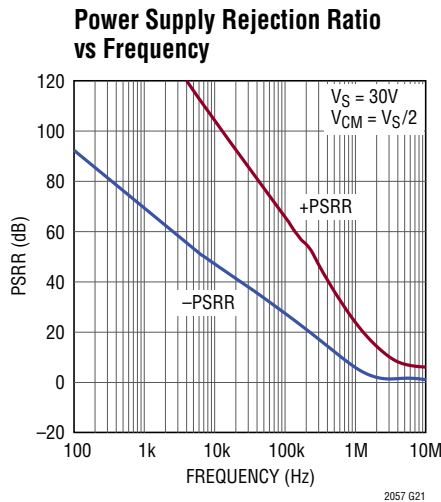
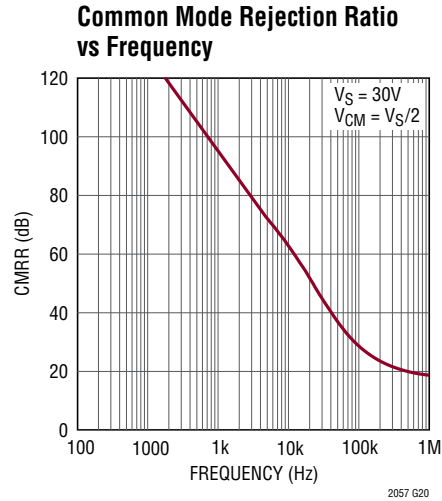
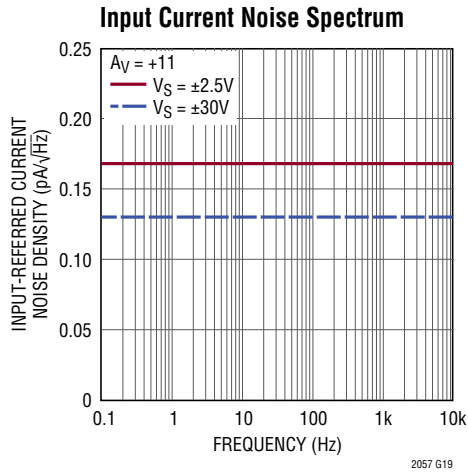
DC to 10Hz Voltage Noise



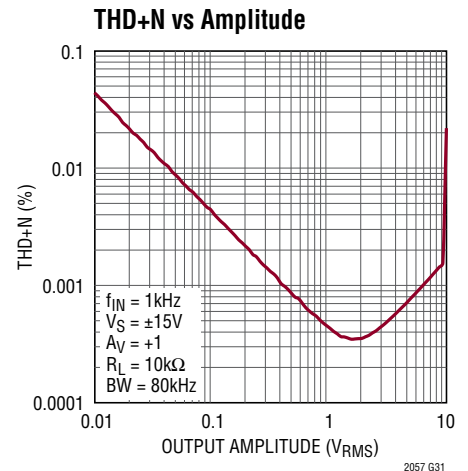
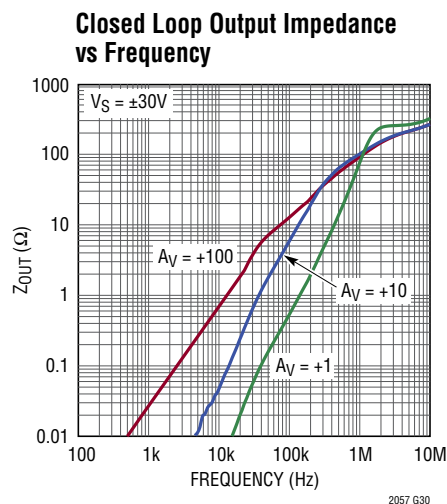
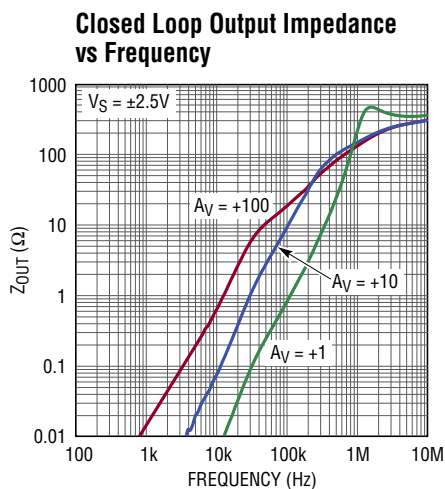
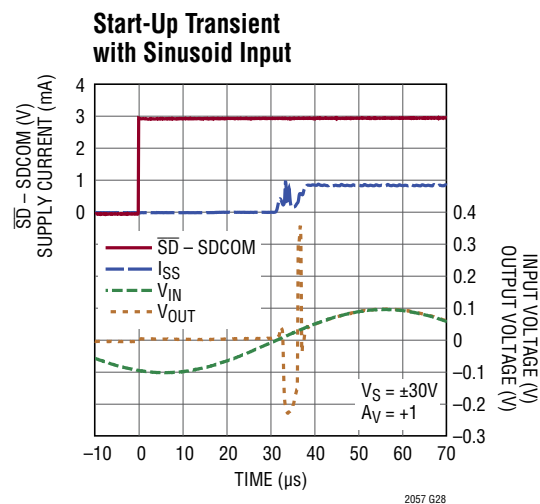
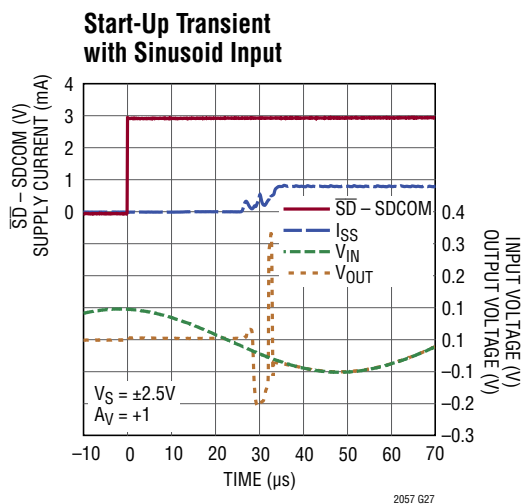
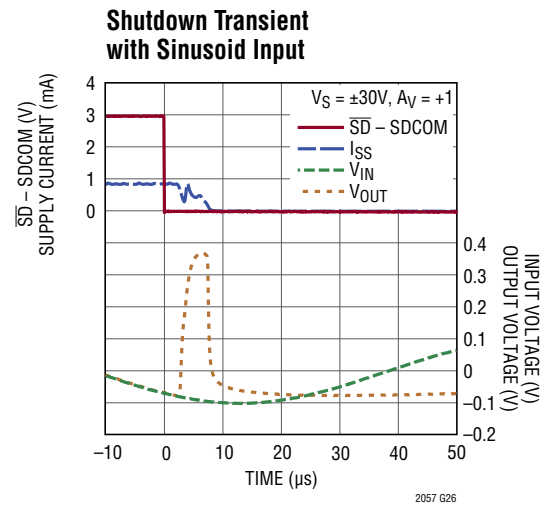
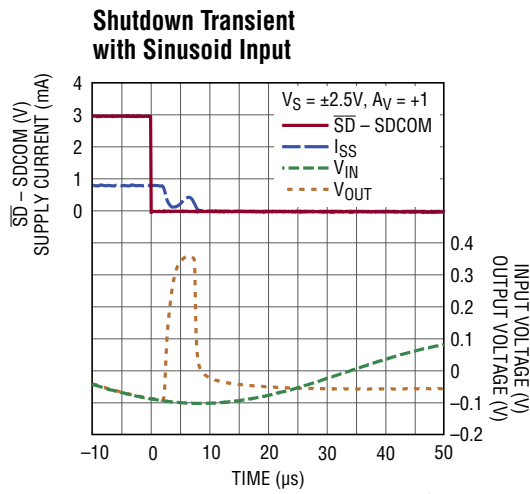
Input Voltage Noise Spectrum



TYPICAL PERFORMANCE CHARACTERISTICS

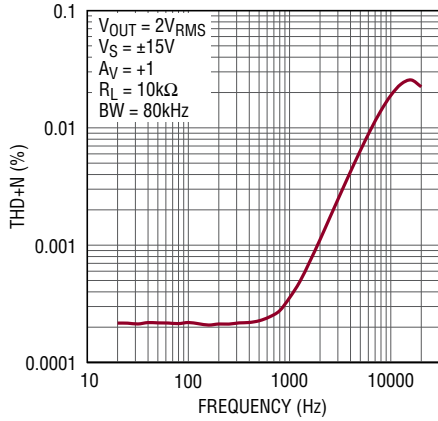


TYPICAL PERFORMANCE CHARACTERISTICS



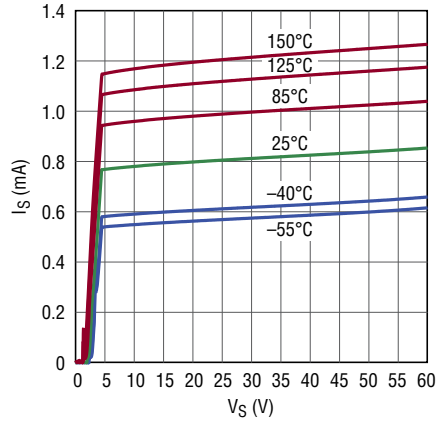
TYPICAL PERFORMANCE CHARACTERISTICS

THD+N vs Frequency



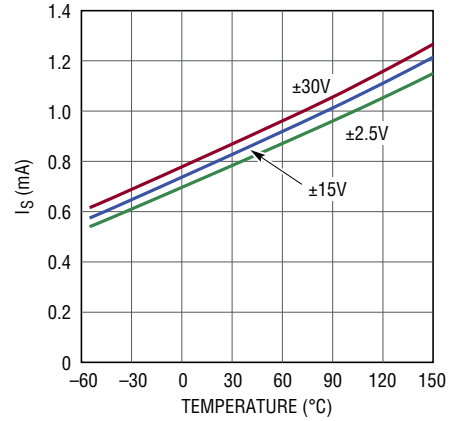
2057 G32

Supply Current vs Supply Voltage



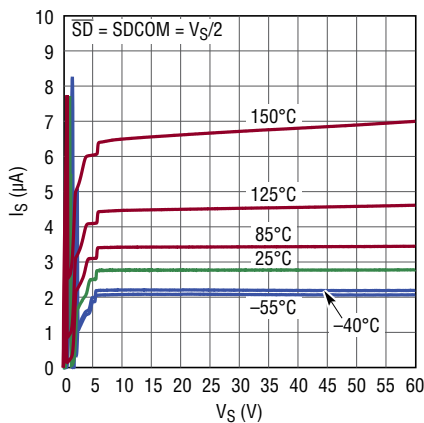
2057 G33

Supply Current vs Temperature



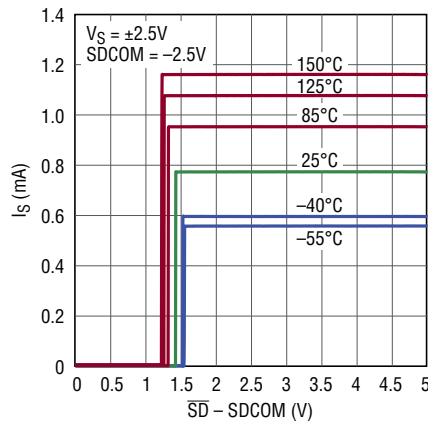
2057 G34

Shutdown Supply Current vs Supply Voltage



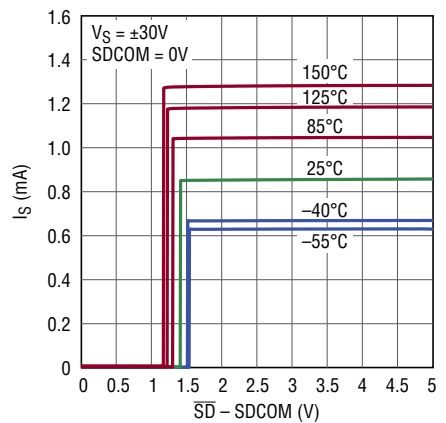
2057 G35

Supply Current vs Shutdown Control Voltage



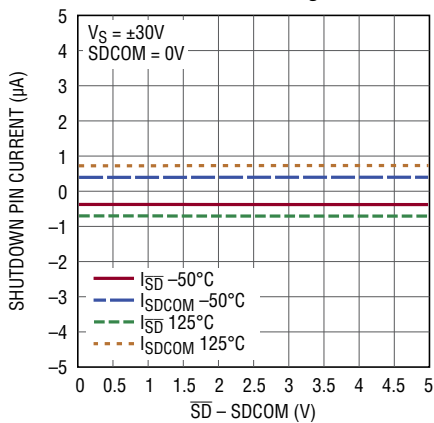
2057 G36

Supply Current vs Shutdown Control Voltage



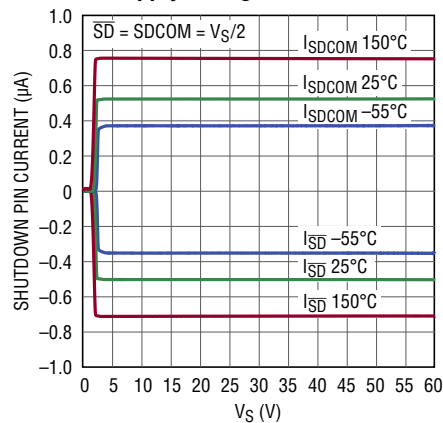
2057 G37

Shutdown Pin Current vs Shutdown Pin Voltage



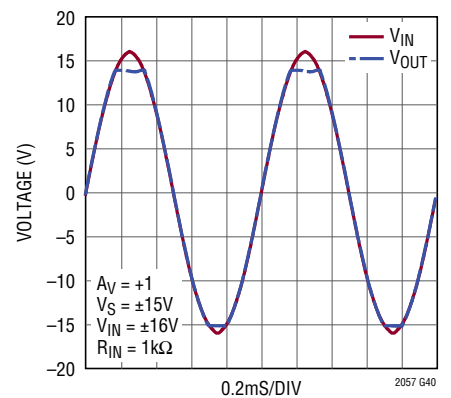
2057 G38

Shutdown Pin Current vs Supply Voltage



2057 G39

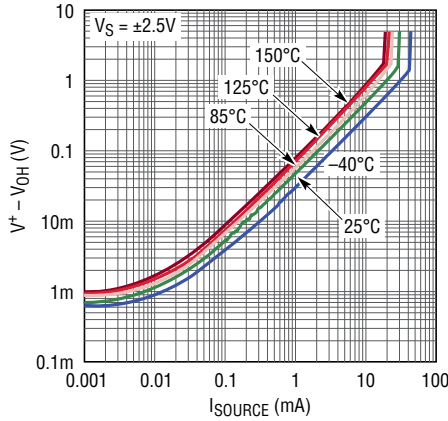
No Phase Reversal



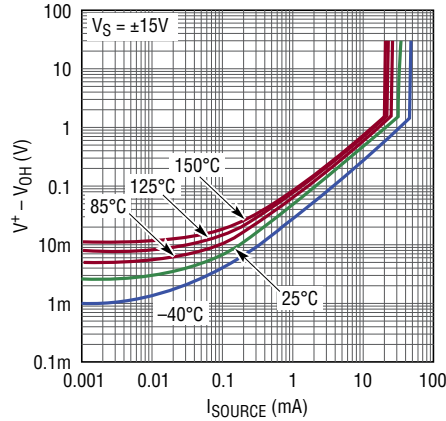
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TYPICAL PERFORMANCE CHARACTERISTICS

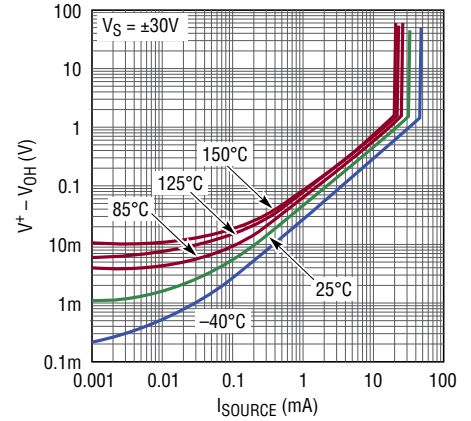
Output Voltage Swing High vs Load Current



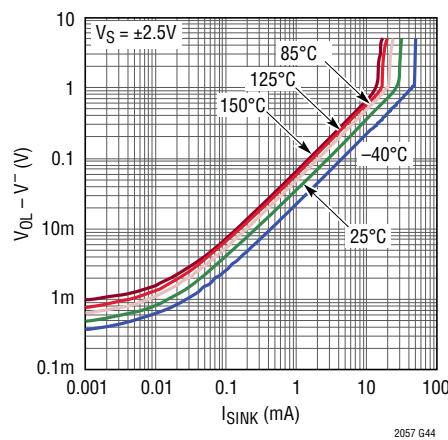
Output Voltage Swing High vs Load Current



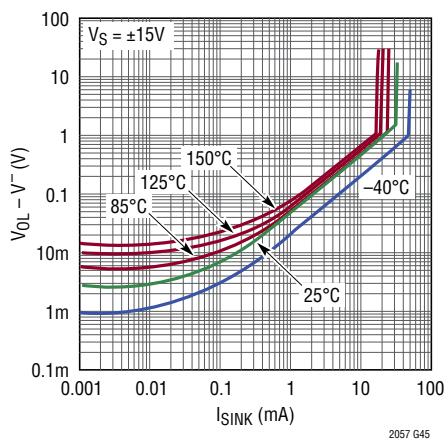
Output Voltage Swing High vs Load Current



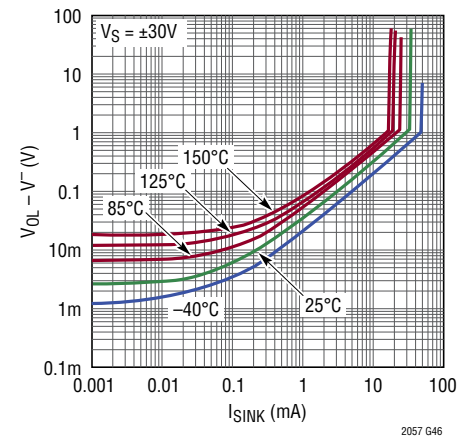
Output Voltage Swing Low vs Load Current



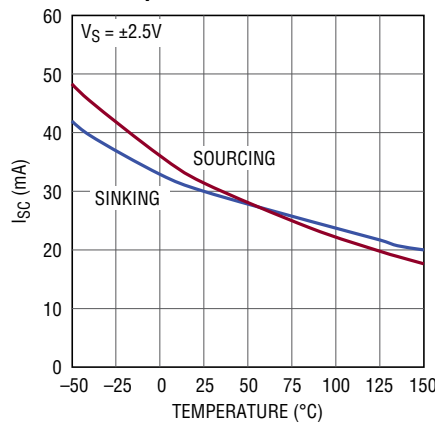
Output Voltage Swing Low vs Load Current



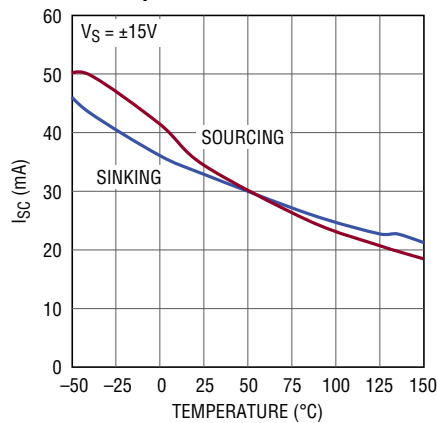
Output Voltage Swing Low vs Load Current



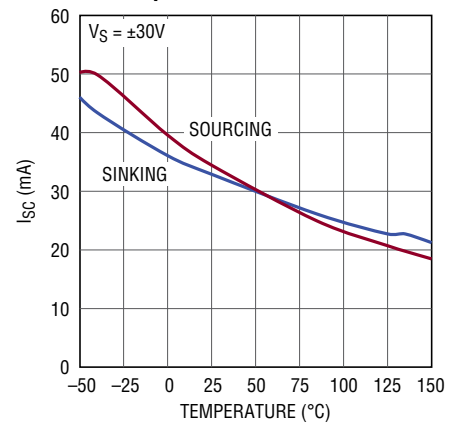
Short-Circuit Current vs Temperature



Short-Circuit Current vs Temperature

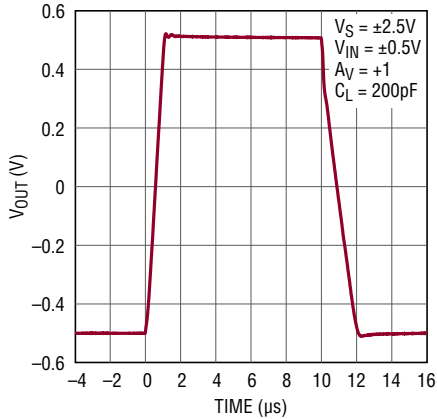


Short-Circuit Current vs Temperature

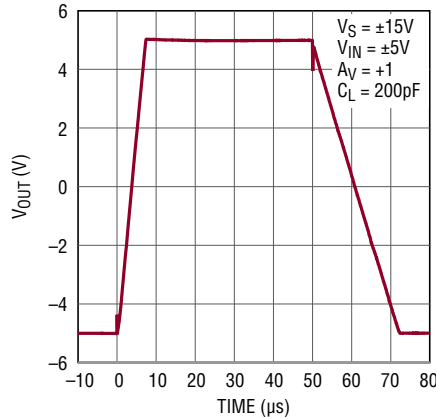


TYPICAL PERFORMANCE CHARACTERISTICS

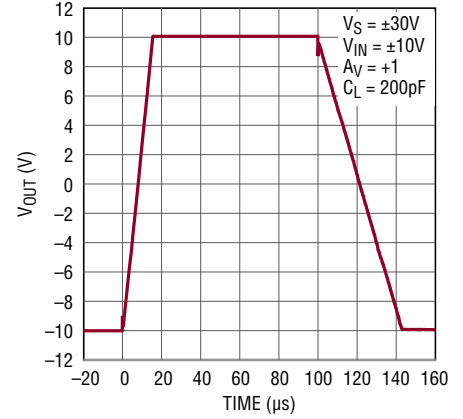
Large Signal Response



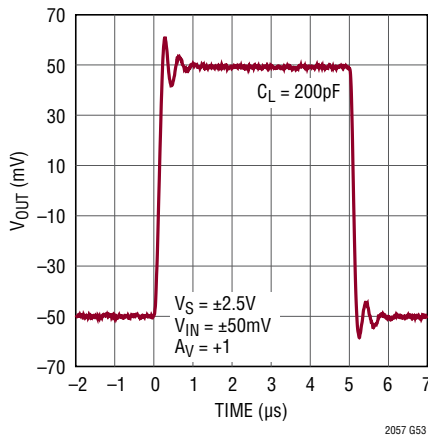
Large Signal Response



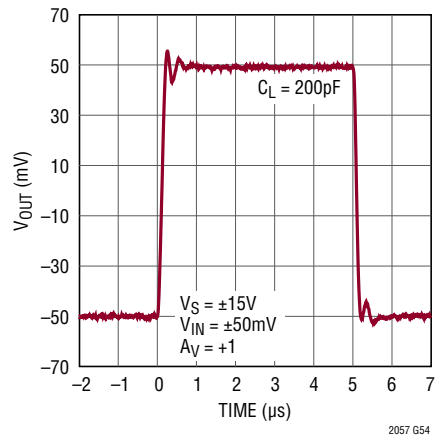
Large Signal Response



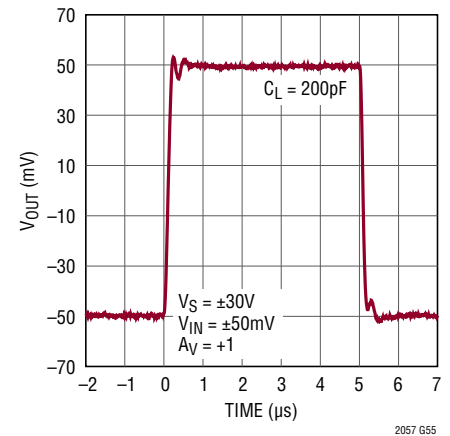
Small Signal Response



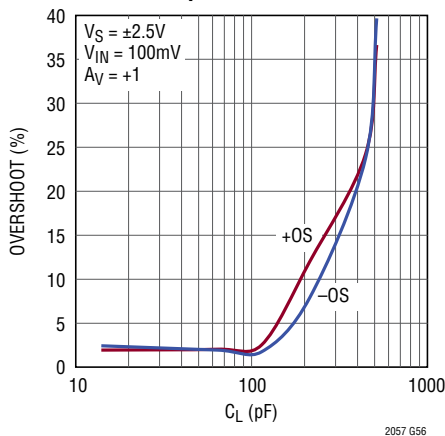
Small Signal Response



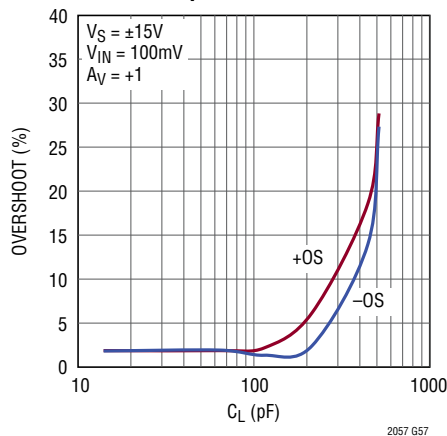
Small Signal Response



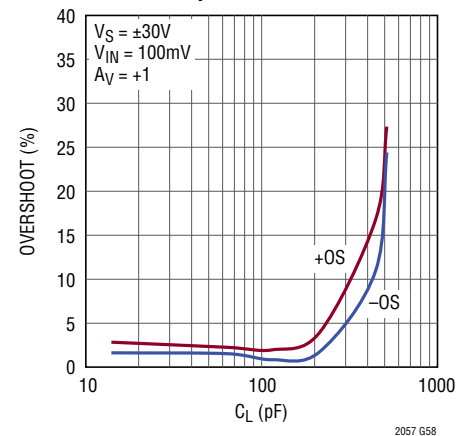
Small Signal Overshoot vs Load Capacitance



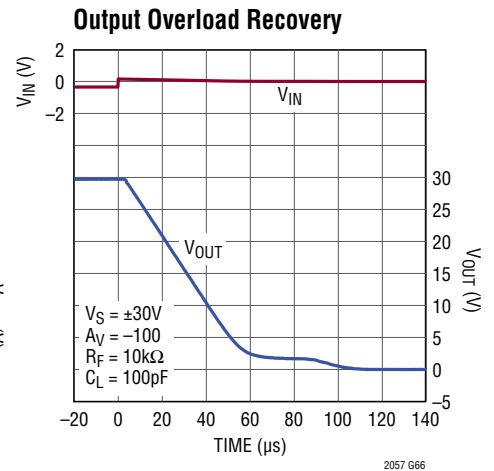
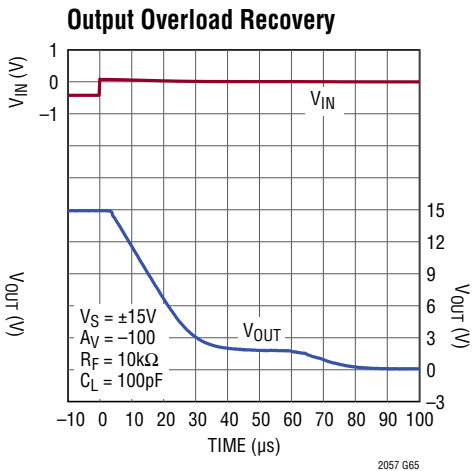
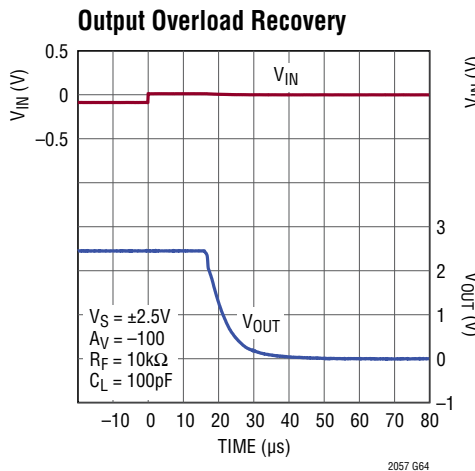
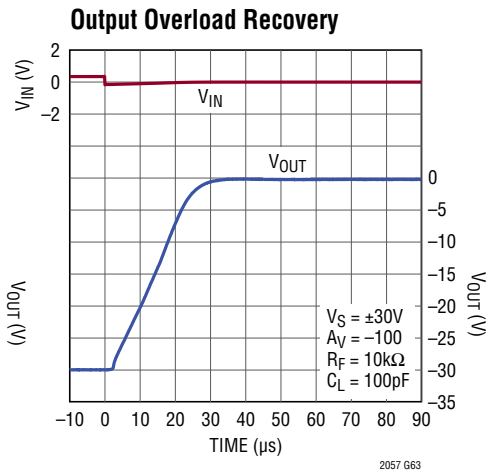
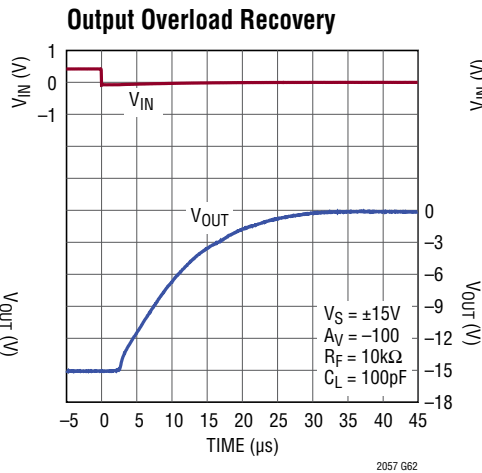
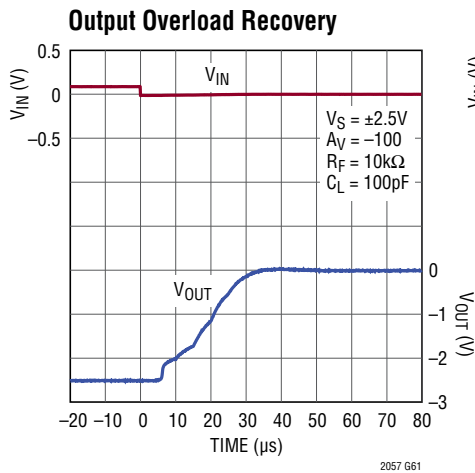
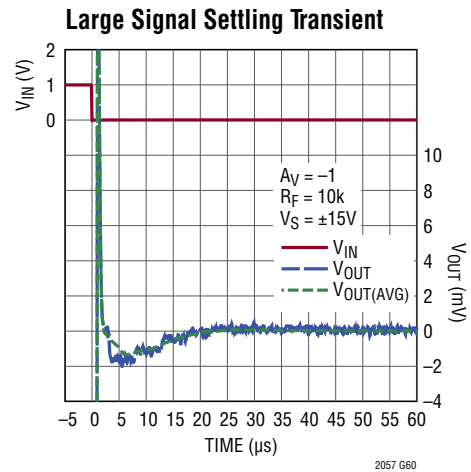
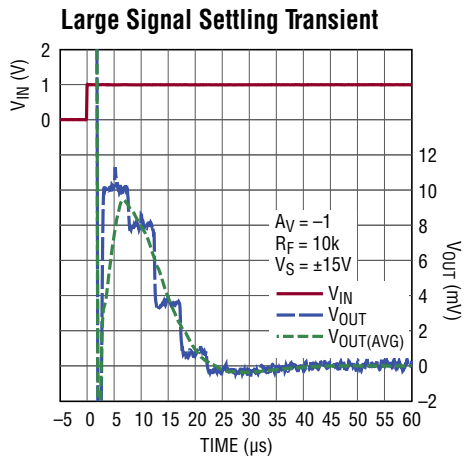
Small Signal Overshoot vs Load Capacitance



Small Signal Overshoot vs Load Capacitance



TYPICAL PERFORMANCE CHARACTERISTICS



PIN FUNCTIONS

MS8 and S8/DD8

$\overline{\text{SD}}$ (Pin 1/Pin 1): Shutdown Control Pin.

$-\text{IN}$ (Pin 2/Pin 2): Inverting Input.

$+\text{IN}$ (Pin 3/Pin 3): Non-Inverting Input.

V^- (Pin 4/Pin 4, 9): Negative Power Supply.

SDCOM (Pin 8/Pin 8): Reference Voltage for $\overline{\text{SD}}$.

V^+ (Pin 7/Pin 7): Positive Power Supply.

OUT (Pin 6/Pin 6): Amplifier Output

NC (Pin 5/Pin 5): No Internal Connection.

MS10

GRD (Pin 1): Guard Ring. No Internal Connection.

$-\text{IN}$ (Pin 2): Inverting Input.

$+\text{IN}$ (Pin 3): Non-Inverting Input.

GRD (Pin 4): Guard Ring. No Internal Connection.

V^- (Pin 5): Negative Power Supply.

$\overline{\text{SD}}$ (Pin 10): Shutdown Control Pin.

SDCOM (Pin 9): Reference Voltage for $\overline{\text{SD}}$.

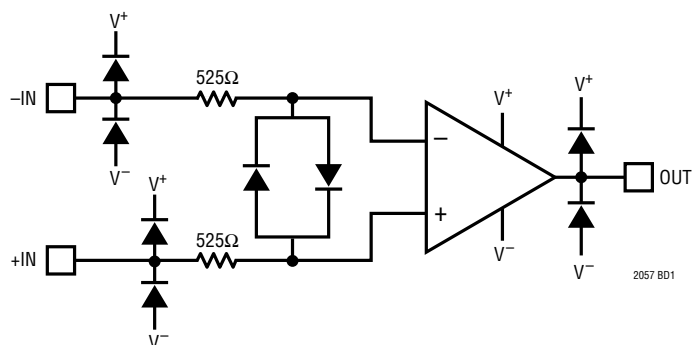
V^+ (Pin 8): Positive Power Supply.

NC (Pin 7): No Internal Connection.

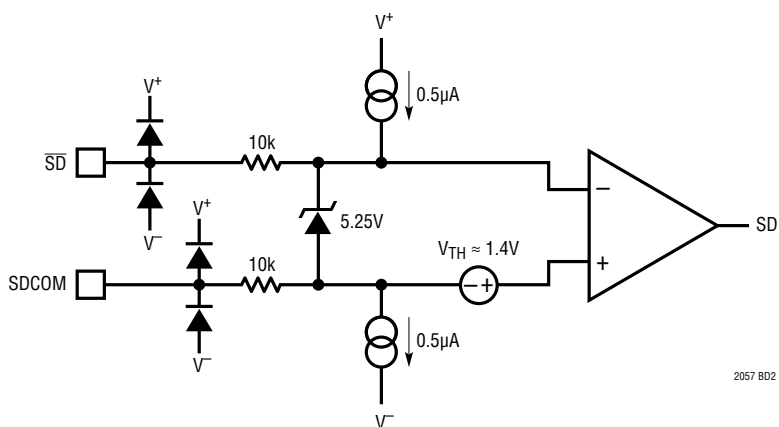
OUT (Pin 6): Amplifier Output.

BLOCK DIAGRAMS

Amplifier



Shutdown Circuit



APPLICATIONS INFORMATION

Input Voltage Noise

Chopper stabilized amplifiers like the LTC2057 achieve low offset and 1/f noise by heterodyning DC and flicker noise to higher frequencies. In a classical chopper stabilized amplifier, this process results in idle tones at the chopping frequency and its odd harmonics.

The LTC2057 utilizes circuitry to suppress these spurious artifacts to well below the offset voltage. The typical ripple magnitude at 100kHz is much less than $1\mu\text{V}_{\text{RMS}}$.

The voltage noise spectrum of the LTC2057 is shown in Figure 1. If lower noise is required, consider one of the following circuits from the Typical Applications section: "DC Stabilized, Ultralow Noise Amplifier" or "Paralleling Choppers to Improve Noise."

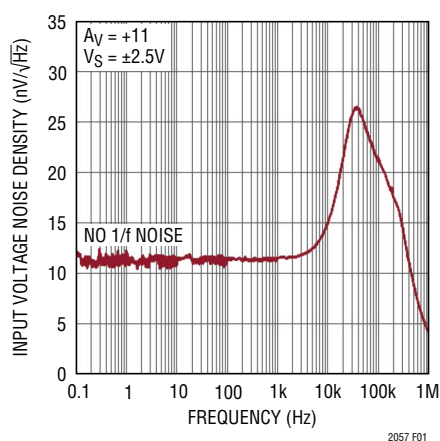


Figure 1. Input Voltage Noise Spectrum

Input Current Noise

For applications with high source impedances, input current noise can be a significant contributor to total output noise. For this reason, it is important to consider noise current interaction with circuit elements placed at an amplifier's inputs.

The current noise spectrum of the LTC2057 is shown in Figure 2. The characteristic curve shows no 1/f behavior. As with all zero-drift amplifiers, there is a significant current noise component at the offset-nulling frequency. This phenomenon is discussed in the Input Bias Current section.

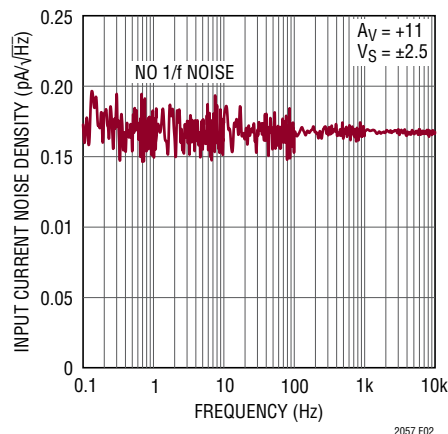


Figure 2. Input Current Noise Spectrum

It is important to note that the current noise is not equal to $2qI_B$. This formula is relevant for base current in bipolar transistors and diode currents, but for most chopper and auto-zero amplifiers with switched inputs, the dominant current noise mechanism is not shot noise.

Input Bias Current

As illustrated in Figure 3, the LTC2057's input bias current originates from two distinct mechanisms. Below 75°C, input bias current is nearly constant with temperature, and is caused by charge injection from the clocked input switches used in offset correction.

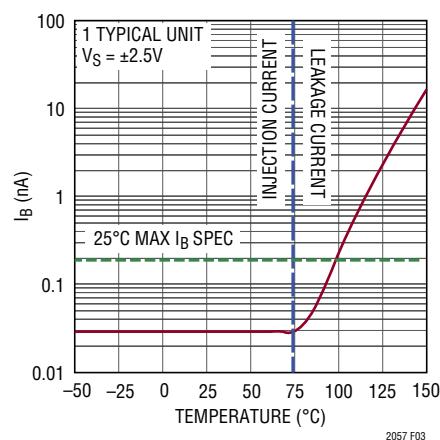


Figure 3. Input Bias Current vs Temperature

APPLICATIONS INFORMATION

The DC average of injection current is the specified input bias current, but this current has a frequency component at the chopping frequency as well. When these small current pulses, typically about $0.7\text{nA}_{\text{RMS}}$, interact with source impedances or gain setting resistors, the resulting voltage spikes are amplified by the closed loop gain. For high impedances, this may cause the 100kHz chopping frequency to be visible in the output spectrum, which is a phenomenon known as clock feed-through.

For zero-drift amplifiers, clock feed-through will be proportional to source impedance and the magnitude of injection current, a measure of which is I_B at 25°C . In order to minimize clock feed-through, keep gain-setting resistors and source impedances as low as possible. If high impedances are required, place a capacitor across the feedback resistor to limit the bandwidth of the closed loop gain. Doing so will effectively filter out the clock feed-through signal.

Injection currents from the two inputs are of equal magnitude but opposite direction. Therefore, input bias current effects due to injection currents will not be canceled by placing matched impedances at both inputs.

Above 75°C , leakage of the ESD protection diodes begins to dominate the input bias current and continues to increase exponentially at elevated temperatures. Unlike injection current, leakage currents are in the same direction for both inputs. Therefore, the output error due to leakage currents

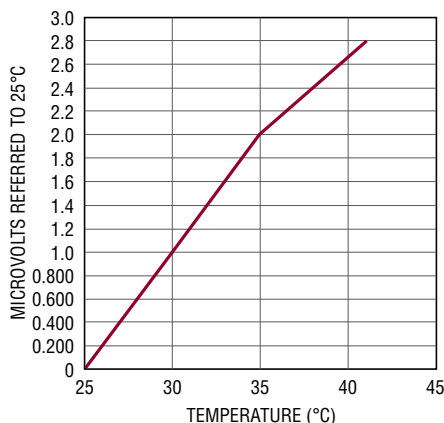
can be mitigated by matching the source impedances seen by the two inputs.

Thermocouple Effects

In order to achieve accuracy on the microvolt level, thermocouple effects must be considered. Any connection of dissimilar metals forms a thermoelectric junction and generates a small temperature-dependent voltage. Also known as the Seebeck Effect, these thermal EMFs can be the dominant error source in low-drift circuits.

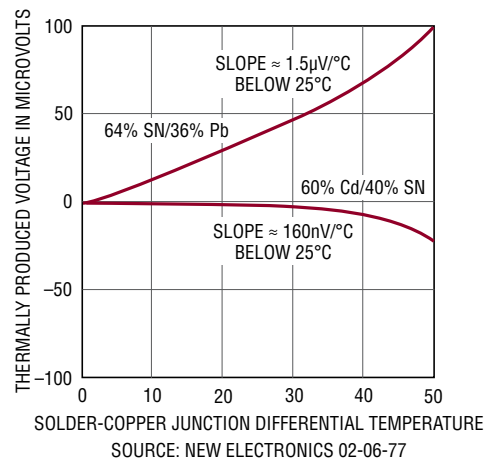
Connectors, switches, relay contacts, sockets, resistors, and solder are all candidates for significant thermal EMF generation. Even junctions of copper wire from different manufacturers can generate thermal EMFs of $200\text{nV}/^\circ\text{C}$, which is over 13 times the maximum drift specification of the LTC2057. Figures 4 and 5 illustrate the potential magnitude of these voltages and their sensitivity to temperature.

In order to minimize thermocouple-induced errors, attention must be given to circuit board layout and component selection. It is good practice to minimize the number of junctions in the amplifier's input signal path and avoid connectors, sockets, switches, and relays whenever possible. If such components are required, they should be selected for low thermal EMF characteristics. Furthermore, the number, type, and layout of junctions should be matched for both inputs with respect to thermal gradients on the circuit board. Doing so may involve deliberately introducing dummy junctions to offset unavoidable junctions.



2057 F04

Figure 4. Thermal EMF Generated by Two Copper Wires From Different Manufacturers

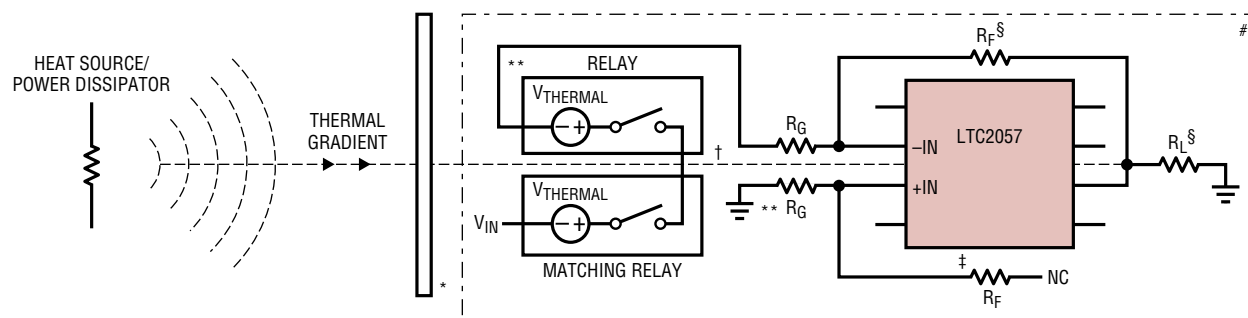


SOURCE: NEW ELECTRONICS 02-06-77

2057 F05

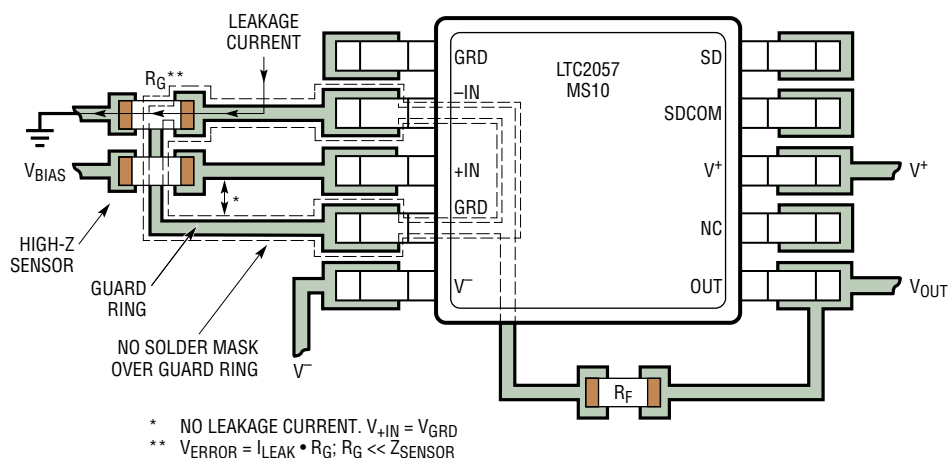
Figure 5. Solder-Copper Thermal EMFs

APPLICATIONS INFORMATION

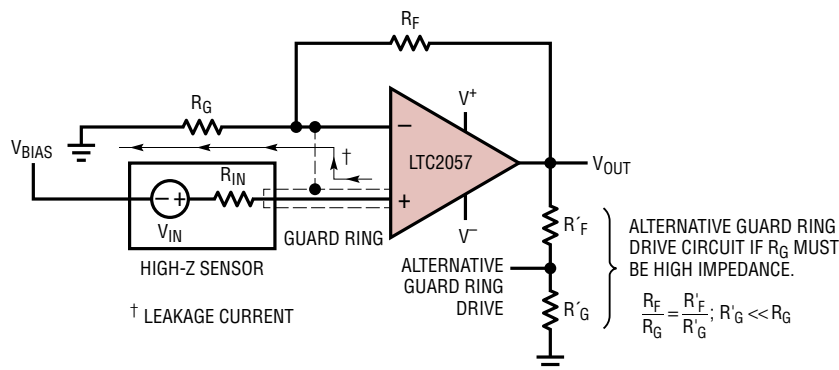


- * CUT SLOTS IN PCB FOR THERMAL ISOLATION.
- ** INTRODUCE DUMMY JUNCTIONS AND COMPONENTS TO OFFSET UNAVOIDABLE JUNCTIONS OR CANCEL THERMAL EMFs.
- † ALIGN INPUTS SYMMETRICALLY WITH RESPECT TO THERMAL GRADIENTS.
- ‡ INTRODUCE DUMMY TRACES AND COMPONENTS FOR SYMMETRICAL THERMAL HEAT SINKING.
- § LOADS AND FEEDBACK CAN DISSIPATE POWER AND GENERATE THERMAL GRADIENTS. BE AWARE OF THEIR THERMAL EFFECTS.
- # COVER CIRCUIT TO PREVENT AIR CURRENTS FROM CREATING THERMAL GRADIENTS.

Figure 6. Techniques for Minimizing Thermocouple-Induced Errors



- * NO LEAKAGE CURRENT. $V_{+IN} = V_{GRD}$
- ** $V_{ERROR} = I_{LEAK} \cdot R_G$; $R_G \ll Z_{SENSOR}$



ALTERNATIVE GUARD RING
DRIVE CIRCUIT IF R_G MUST
BE HIGH IMPEDANCE.

$$\frac{R_F}{R_G} = \frac{R'_F}{R'_G}; R'_G \ll R_G$$

2057 F07a

Figure 7a. Example Layout of Non-Inverting Amplifier with Leakage Guard Ring

APPLICATIONS INFORMATION

Air currents can also lead to thermal gradients and cause significant noise in measurement systems. It is important to prevent airflow across sensitive circuits. Doing so will often reduce thermocouple noise substantially.

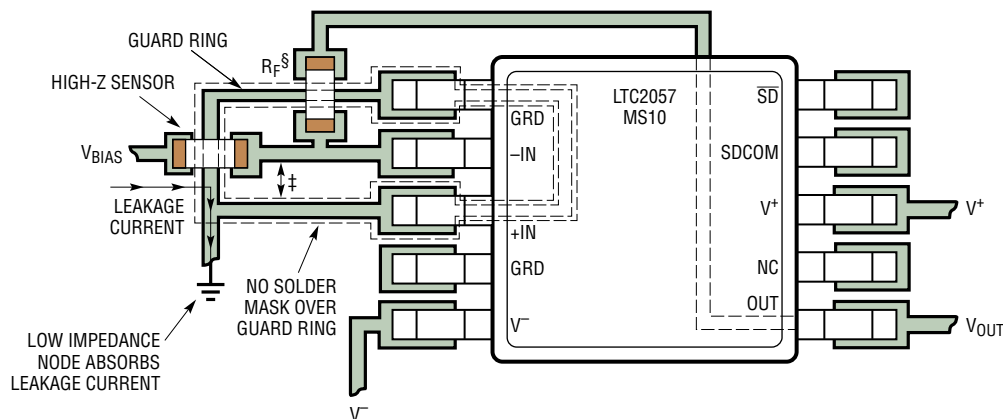
A summary of techniques can be found in Figure 6.

Leakage Effects

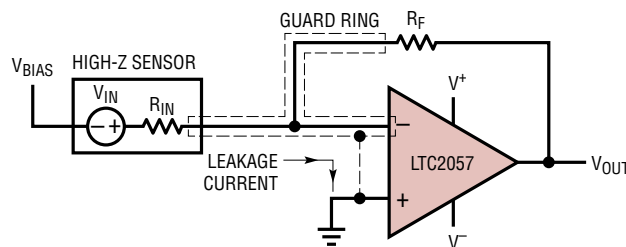
Leakage currents into high impedance signal nodes can easily degrade measurement accuracy of sub-nanoamp signals. High voltage and high temperature applications are especially susceptible to these issues. Quality insulation materials should be used, and insulating surfaces should be cleaned to remove fluxes and other residues. For humid environments, surface coating may be necessary to provide a moisture barrier.

Board leakage can be minimized by encircling the input connections with a guard ring operated at a potential very close to that of the inputs. The ring must be tied to a low impedance node. For inverting configurations, the guard ring should be tied to the potential of the positive input (+IN). For non-inverting configurations, the guard ring should be tied to the potential of the negative input (–IN). In order for this technique to be effective, the guard ring must not be covered by solder mask. Ringing both sides of the printed circuit board may be required. See Figures 7a and 7b for examples of proper layout.

For low-leakage applications, the LTC2057 is available in an MS10 package with a special pinout that facilitates the layout of guard ring structures. The pins adjacent to the inputs have no internal connection, allowing a guard ring to be routed through them.



† NO LEAKAGE CURRENT. $V_{-IN} = V_{GRD}$
 § AVOID DISSIPATING SIGNIFICANT AMOUNTS OF POWER IN THIS RESISTOR. IT WILL GENERATE THERMAL GRADIENTS WITH RESPECT TO THE INPUT PINS AND LEAD TO THERMOCOUPLE-INDUCED ERROR. THERMALLY ISOLATE OR ALIGN WITH INPUTS IF RESISTOR WILL CAUSE HEATING.



LEAKAGE CURRENT IS ABSORBED BY GROUND INSTEAD OF CAUSING A MEASUREMENT ERROR.

2057 F07b

Figure 7b. Example Layout of Inverting Amplifier with Leakage Guard Ring

APPLICATIONS INFORMATION

Power Dissipation

Since the LTC2057/LTC2057HV is capable of operating at >30V total supply, care should be taken with respect to power dissipation in the amplifier. When driving heavy loads at high voltages, use the θ_{JA} of the package to estimate the resulting die-temperature rise and take measures to ensure that the resulting junction temperature does not exceed specified limits. PCB metallization and heat sinking should also be considered when high power dissipation is expected. Thermal information for all packages can be found in the Pin Configuration section.

Electrical Overstress

Absolute Maximum Ratings should not be exceeded. Avoid driving the input and output pins beyond the rails, especially at supply voltages approaching 60V. If these fault conditions cannot be prevented, a series resistor at the pin of interest should help to limit the input current and reduce the possibility of device damage. This technique is shown in Figure 8.

Keep the value of the current limiting resistance as low as possible to avoid adding noise and error voltages from interaction with input bias currents but high enough to protect the device. Resistances up to 2k will not seriously impact noise or precision.

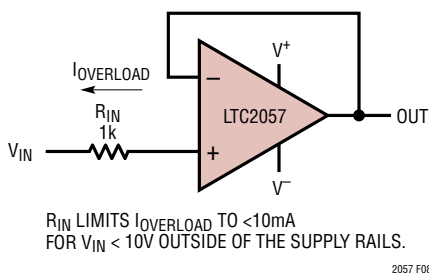


Figure 8. Using a Resistor to Limit Input Current

Shutdown Mode

The LTC2057/LTC2057HV features a shutdown mode for low-power applications. In the OFF state, the amplifier draws less than 11 μ A of supply current under all normal operating conditions, and the output presents a high-impedance to external circuitry.

Shutdown control is accomplished through differential signaling. This method allows for low voltage digital control logic to operate independently of the amplifier's high voltage supply rails.

Shutdown operation is accomplished by tying SDCOM to logic ground and $\overline{SD}$ to a 3V or 5V logic signal. A summary of control logic and operating ranges is shown in Tables 1 and 2.

Table 1. Shutdown Control Logic

SHUTDOWN PIN CONDITION	AMPLIFIER STATE
$\overline{SD}$ = Float, SDCOM = Float	ON
$\overline{SD}$ – SDCOM > 2V	ON
$\overline{SD}$ – SDCOM < 0.8V	OFF

Table 2. Operating Voltage Range for Shutdown Pins

	MIN	MAX
$\overline{SD}$ – SDCOM	–0.2V	5.2V
SDCOM	V [–]	V ⁺ – 2V
$\overline{SD}$	V [–]	V ⁺

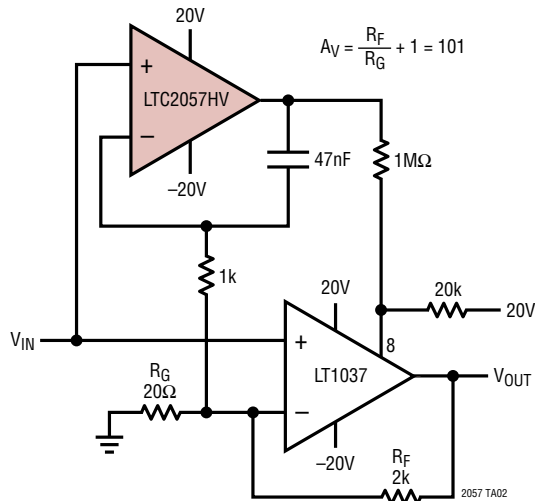
If the shutdown feature is not required, $\overline{SD}$ and SDCOM may be left floating. Internal circuitry will automatically keep the amplifier in the ON state.

For operation in noisy environments, a capacitor between $\overline{SD}$ and SDCOM is recommended to prevent noise from changing the shutdown state.

When there is a danger of $\overline{SD}$ and SDCOM being pulled beyond the supply rails, resistance in series with the shutdown pins is recommended to limit the resulting current.

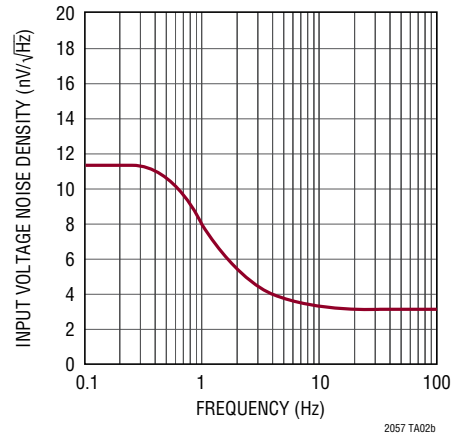
TYPICAL APPLICATIONS

DC Stabilized, Ultralow Noise Composite Amplifier

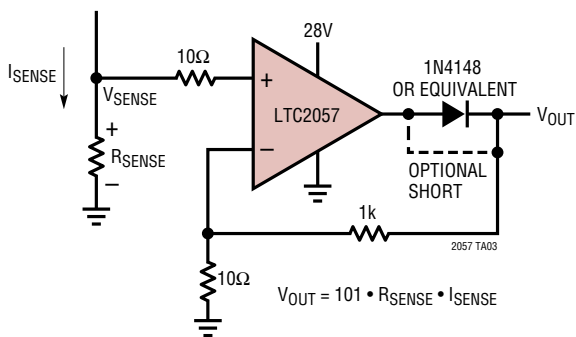


COMPOSITE AMPLIFIER COMBINES THE EXCELLENT BROADBAND NOISE PERFORMANCE OF THE LT1037 WITH THE ZERO-DRIFT PROPERTIES OF THE LTC2057. THE RESULTING CIRCUIT HAS MICROVOLT ACCURACY, SUPPRESSED $1/f$ NOISE, AND LOW BROADBAND NOISE.

Input Voltage Noise Spectrum of Composite Amplifier

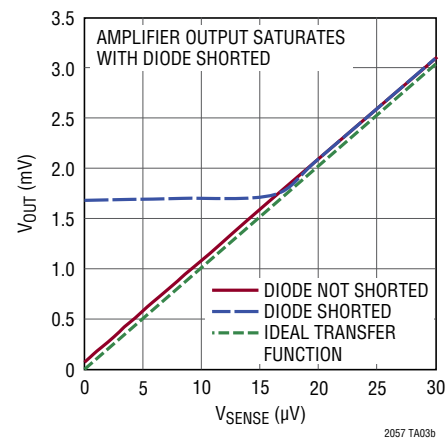


Low-Side Current Sense Amplifier



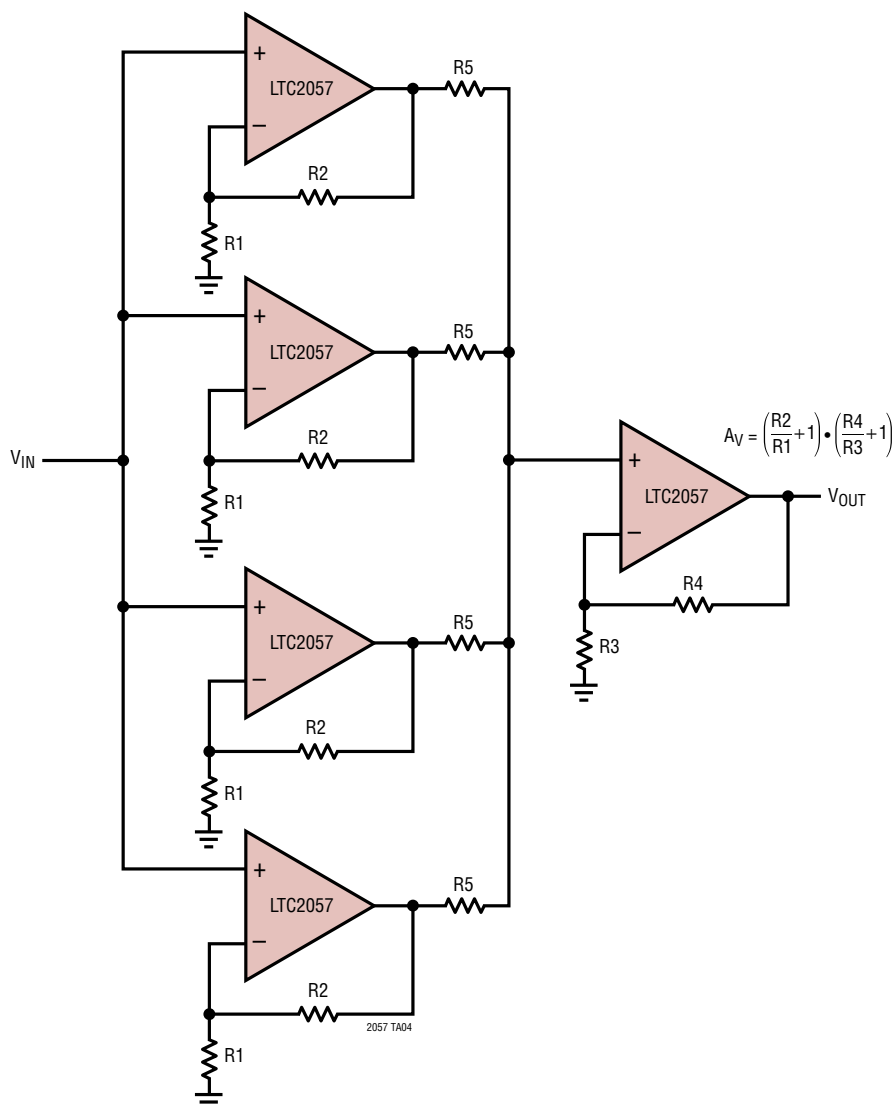
$$V_{OUT} = 101 \cdot R_{SENSE} \cdot I_{SENSE}$$

Low-Side Current Sense Amplifier Transfer Function



TYPICAL APPLICATIONS

Paralleling Choppers to Improve Noise



$$\text{DC TO 10Hz NOISE} = \frac{200\text{nV}_{\text{P-P}}}{\sqrt{N}}, e_n = \frac{11\text{nV}/\sqrt{\text{Hz}}}{\sqrt{N}}, i_n = \sqrt{N} \cdot 170\text{fA}/\sqrt{\text{Hz}}, I_B < N \cdot 200\text{pA (MAX)}$$

WHERE N IS THE NUMBER OF PARALLELED INPUT AMPLIFIERS.

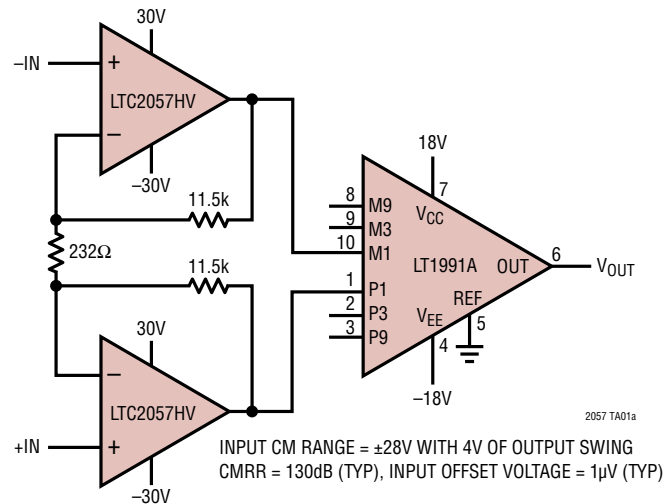
FOR N = 4, DC TO 10Hz NOISE = 100nV_{P-P}, $e_n = 5.5\text{nV}/\sqrt{\text{Hz}}$, $i_n = 340\text{fA}/\sqrt{\text{Hz}}$, $I_B < 800\text{pA (MAX)}$.

R₅ SHOULD BE A FEW HUNDRED OHMS TO ISOLATE AMPLIFIER OUTPUTS WITHOUT CONTRIBUTING SIGNIFICANTLY TO NOISE OR I_B-INDUCED ERROR.

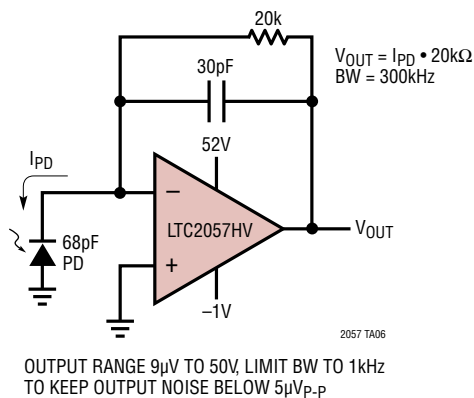
$$\left(\frac{R_2}{R_1} + 1\right) \gg \sqrt{N} \text{ FOR OUTPUT AMPLIFIER NOISE TO BE INSIGNIFICANT.}$$

TYPICAL APPLICATIONS

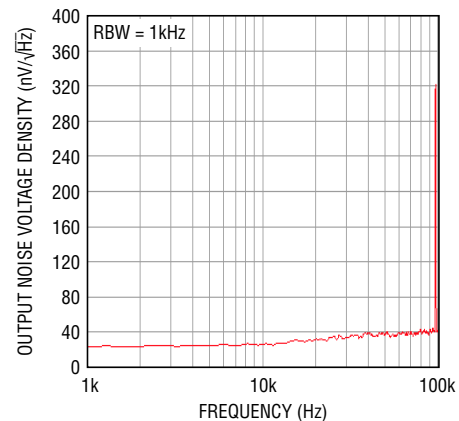
Wide Input Range Precision Gain-of-100 Instrumentation Amplifier



Ultra-Precision, 135dB Dynamic Range Photodiode Amplifier



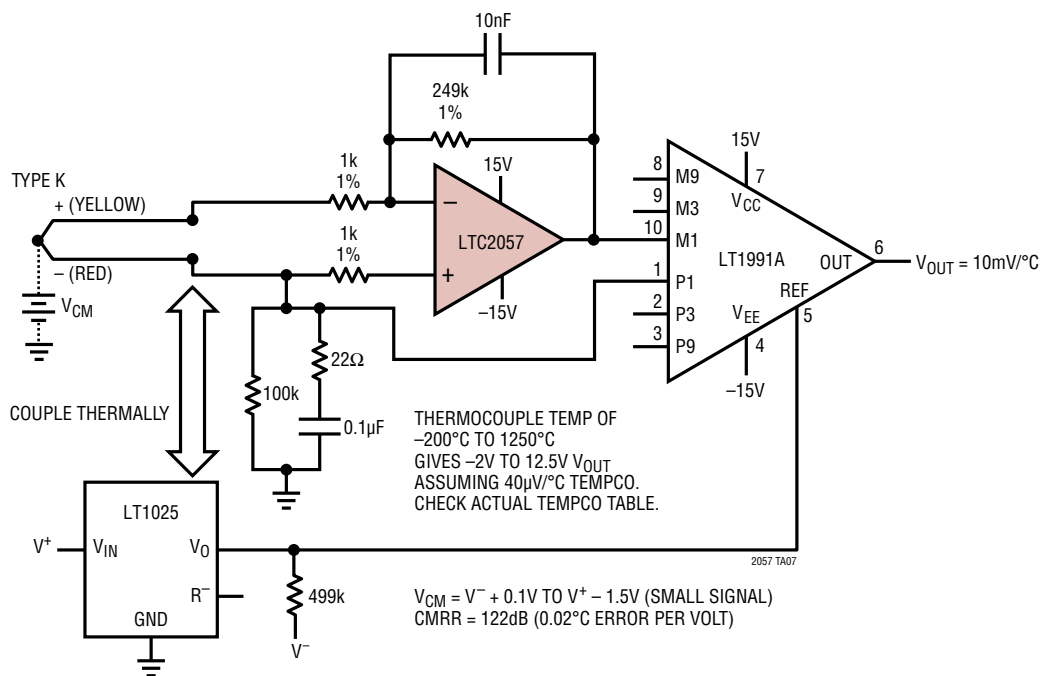
Output Noise Spectrum of Photodiode Amplifier



NOISE FLOOR IS ONLY SLIGHTLY ABOVE THE $20k\Omega$ RESISTOR'S $18nV/\sqrt{Hz}$.
CLOCK FEEDTHROUGH IS VISIBLE NEAR 100kHz WITH AMPLITUDE OF $10\mu V_{RMS}$ OUTPUT REFERRED OR $0.5nA_{RMS}$ INPUT REFERRED.

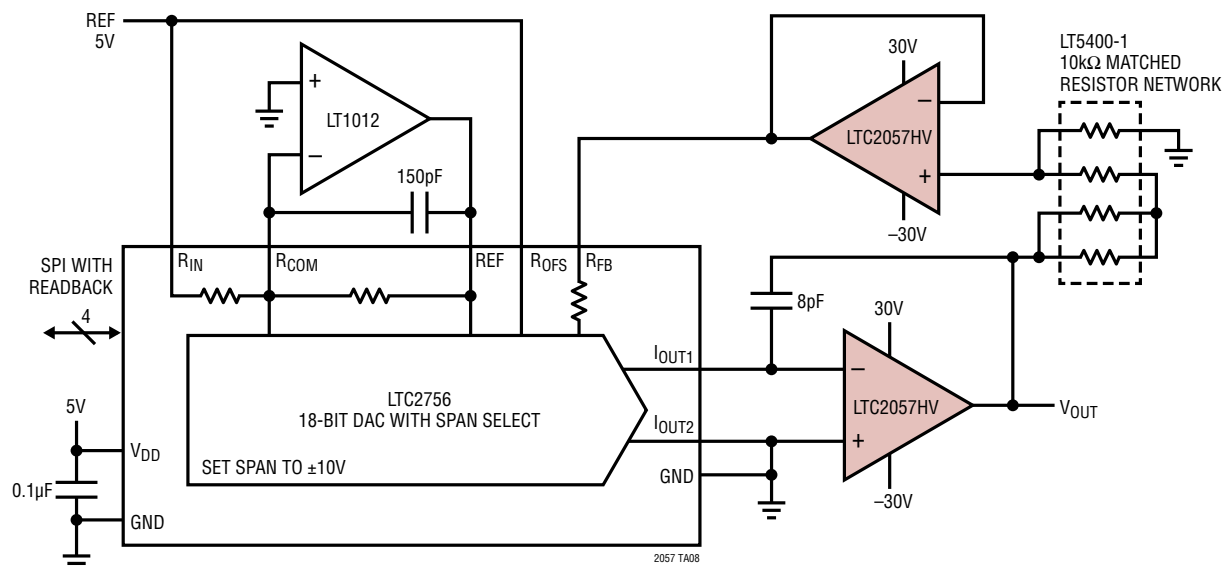
TYPICAL APPLICATIONS

Differential Thermocouple Amplifier

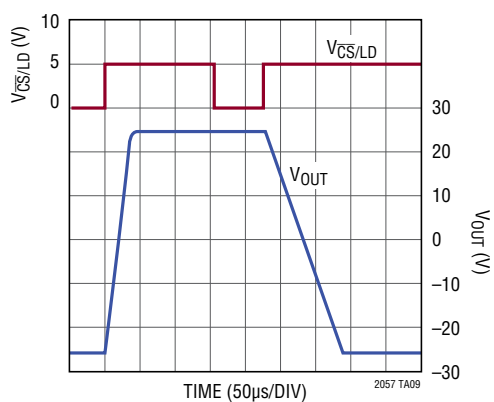


TYPICAL APPLICATIONS

18-Bit DAC with $\pm 25\text{V}$ Output Swing



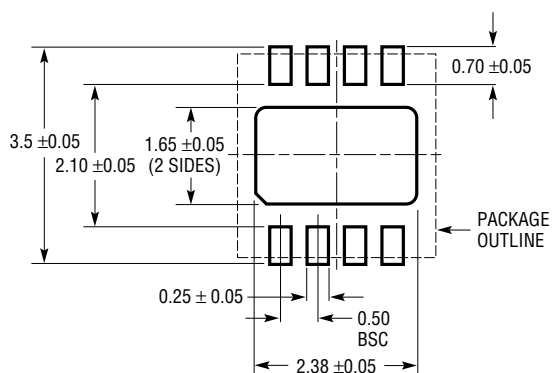
Time Domain Response



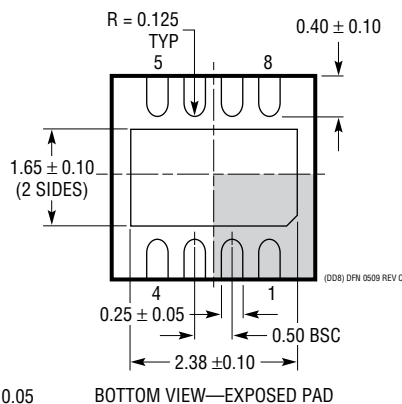
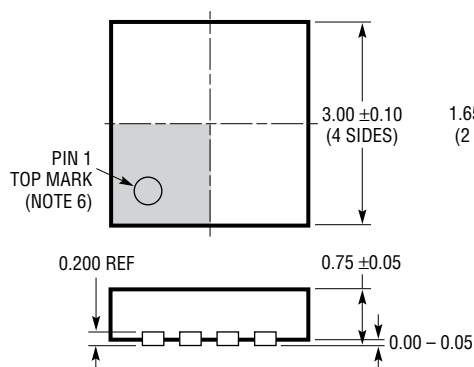
PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/designtools/packaging/> for the most recent package drawings.

DD8 Package
8-Lead Plastic DFN (3mm × 3mm)
 (Reference LTC DWG # 05-08-1698 Rev C)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS
 APPLY SOLDER MASK TO AREAS THAT ARE NOT SOLDERED



NOTE:

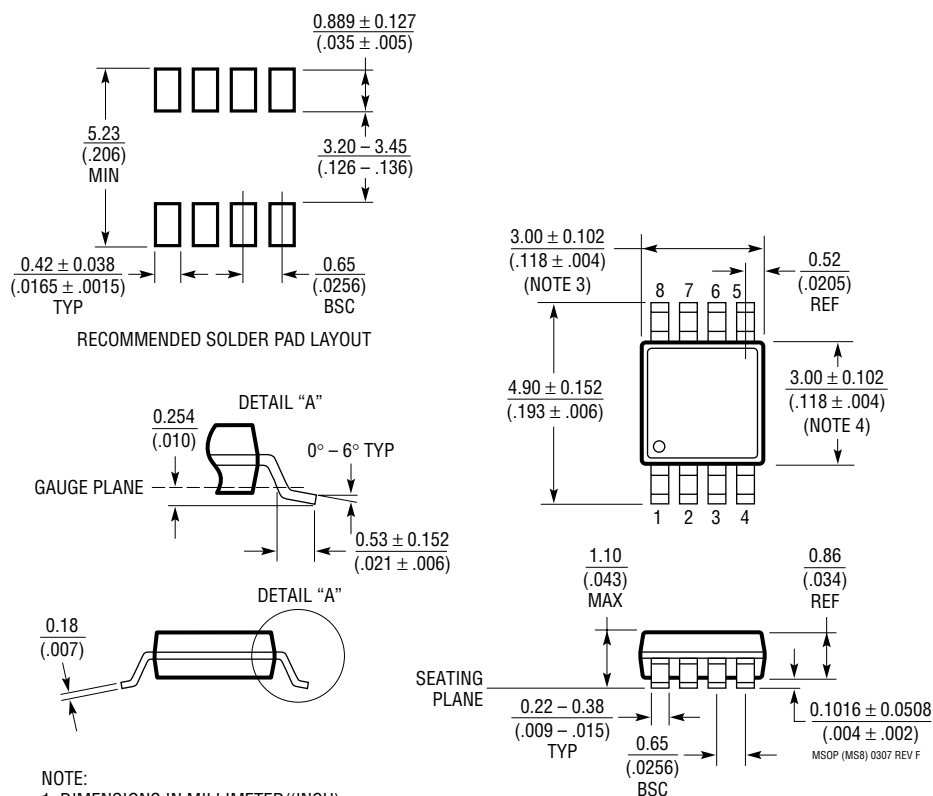
1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE M0-229 VARIATION OF (WEED-1)
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON TOP AND BOTTOM OF PACKAGE

PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/designtools/packaging/> for the most recent package drawings.

MS8 Package 8-Lead Plastic MSOP

(Reference LTC DWG # 05-08-1660 Rev F)

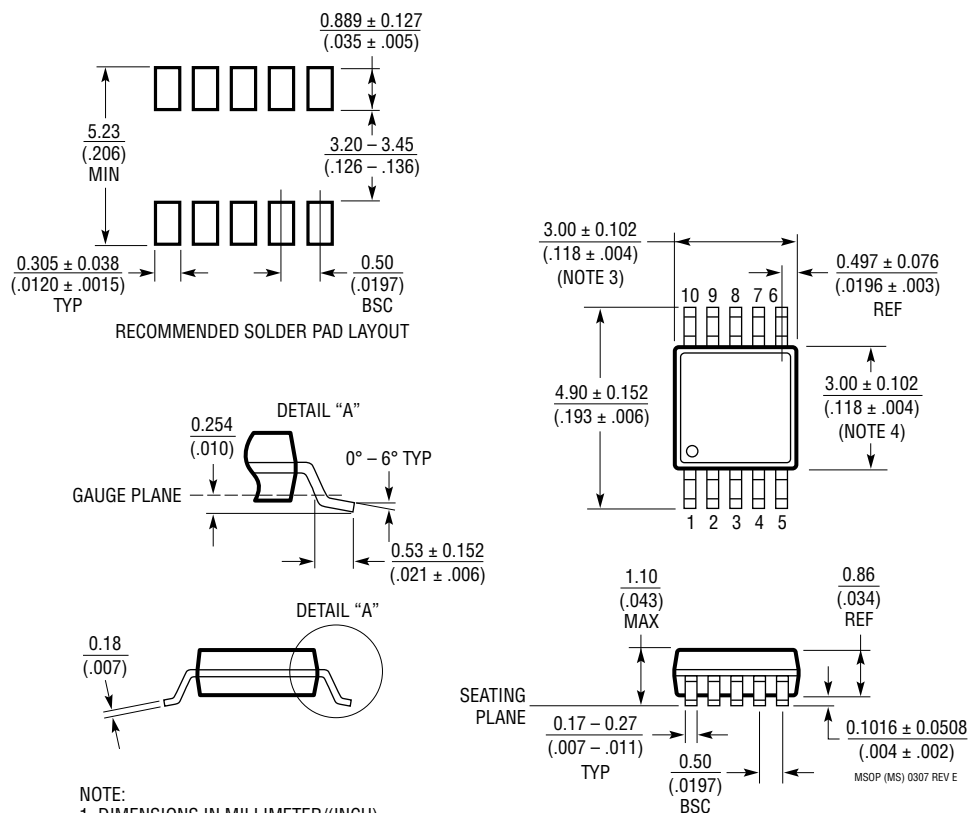


PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/designtools/packaging/> for the most recent package drawings.

MS Package 10-Lead Plastic MSOP

(Reference LTC DWG # 05-08-1661 Rev E)



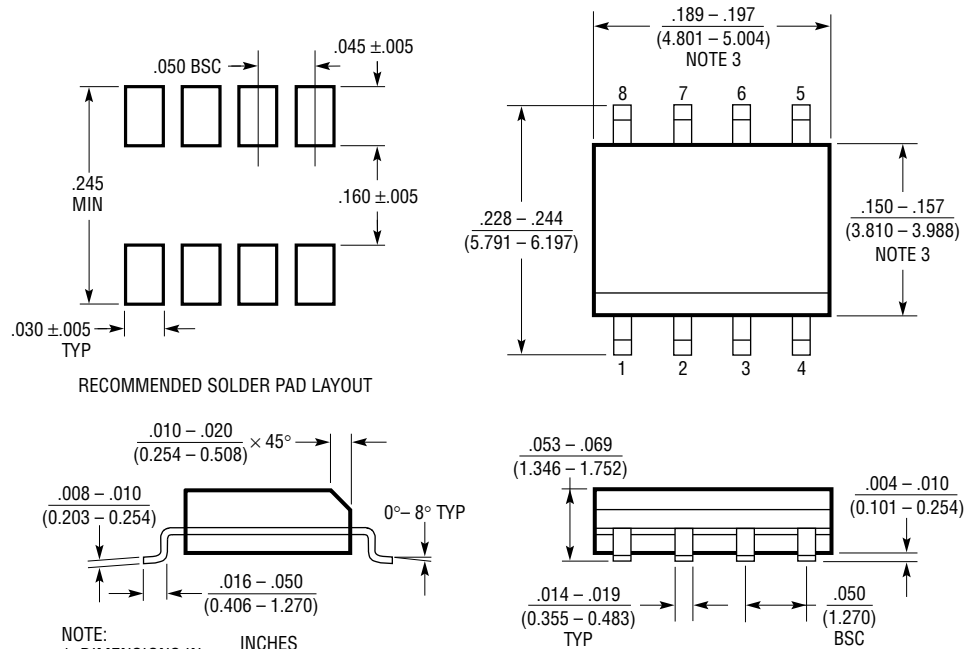
NOTE:

1. DIMENSIONS IN MILLIMETER/(INCH)
2. DRAWING NOT TO SCALE
3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/designtools/packaging/> for the most recent package drawings.

S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610 Rev G)



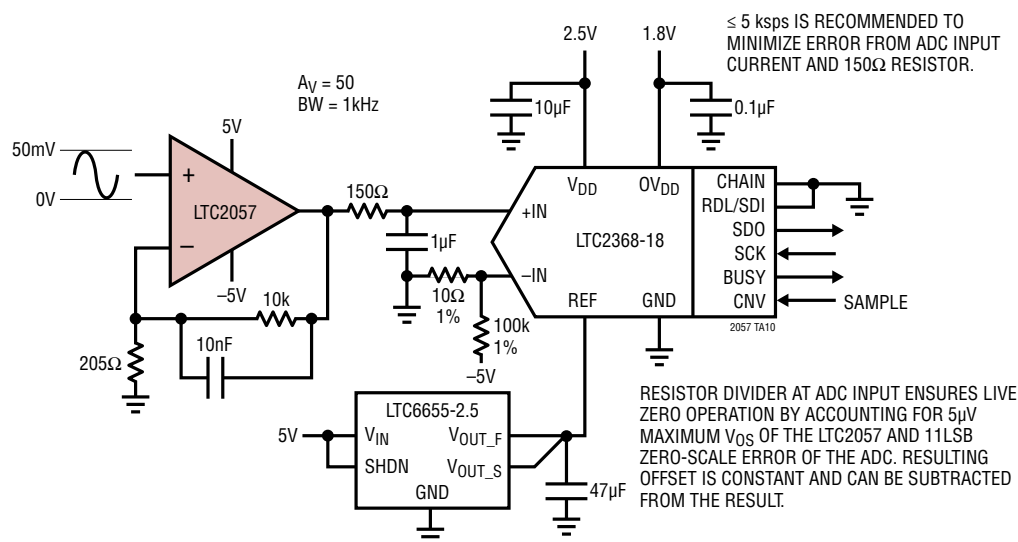
- NOTE:
1. DIMENSIONS IN $\frac{\text{INCHES}}{\text{(MILLIMETERS)}}$
 2. DRAWING NOT TO SCALE
 3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED $.006''$ (0.15mm)
 4. PIN 1 CAN BE BEVEL EDGE OR A DIMPLE

S08 REV G 0212

Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

TYPICAL APPLICATION

Microvolt Precision 18-Bit ADC Driver



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC2050HV	Zero-Drift Operational Amplifier	$3\mu\text{V } V_{OS}$, 2.7V to 12V V_S , 1.5mA I_S , RR Output
LTC2051HV/ LTC2052HV	Dual/Quad, Zero-Drift Operational Amplifier	$3\mu\text{V } V_{OS}$, 2.7V to 12V V_S , 1.5mA I_S , RR Output
LTC2053	Precision, Rail-to-Rail, Zero-Drift, Resistor-Programmable Instrumentation Amplifier	$10\mu\text{V } V_{OS}$, 2.7V to 11V V_S , 1.3mA I_S , RRIO
LTC2054HV/ LTC2055HV	Micropower, Single/Dual, Zero-Drift Operational Amplifier	$5\mu\text{V } V_{OS}$, 2.7V to 12V V_S , 0.2mA I_S , RRIO
LTC6652	Precision, Low Drift, Low Noise, Buffered Reference	$5\text{ppm}/^\circ\text{C}$, 0.05% Initial Accuracy, 2.1ppm_{P-P} Noise
LT6654	Precision, Wide Supply, High Output Drive, Low Noise Reference	$10\text{ppm}/^\circ\text{C}$, 0.05% Initial Accuracy, 1.6ppm_{P-P} Noise
LTC6655	0.25ppm Noise, Low Drift, Precision, Buffered Reference Family	$2\text{ppm}/^\circ\text{C}$, 0.025% Initial Accuracy, 0.25ppm_{P-P} Noise
LT6016/LT6017	Dual/Quad, 76V Over-The-Top® Input Operational Amplifier	$50\mu\text{V } V_{OS}$, 3V to 50V V_S , 0.335mA I_S , RRIO
LTC6090	140V Operational Amplifier	$50\text{pA } I_B$, $1.6\text{mV } V_{OS}$, 9.5V to 140V V_S , 4.5mA I_S , RR Output
LT5400	Quad Matched Resistor Network	$\pm 0.01\%$, $\pm 0.2\text{ppm}/^\circ\text{C}$ Matching